

Principles of Materials Design for Efficient Spin-State Switching in Ultrathin Layers

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ESMoINa-2026
Gandía, Spain
May 21, 2026



Outline

- ❖ Spin Crossover: Quick Introduction
- ❖ Spin Crossover at Nanoscale
 - Thin films
 - Ultrathin films
 - Single molecules
- ❖ Spin Crossover Films via Gas Phase
- ❖ Spin Crossover Films via Exfoliation



Intro: Spin Crossover

Entropy driven transition

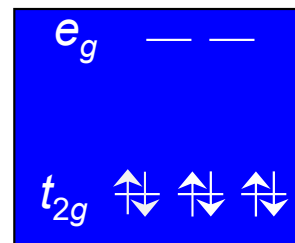
Observed for d^4 , d^5 , d^6 , d^7 ions

Triggered by changes in temperature, pressure, or photoexcitation

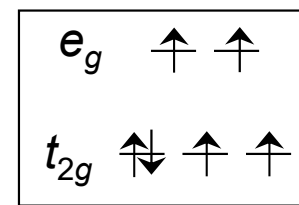
Dramatic changes in:

- magnetic moment
- **M-L bond lengths**
- **absorption spectrum (color)**

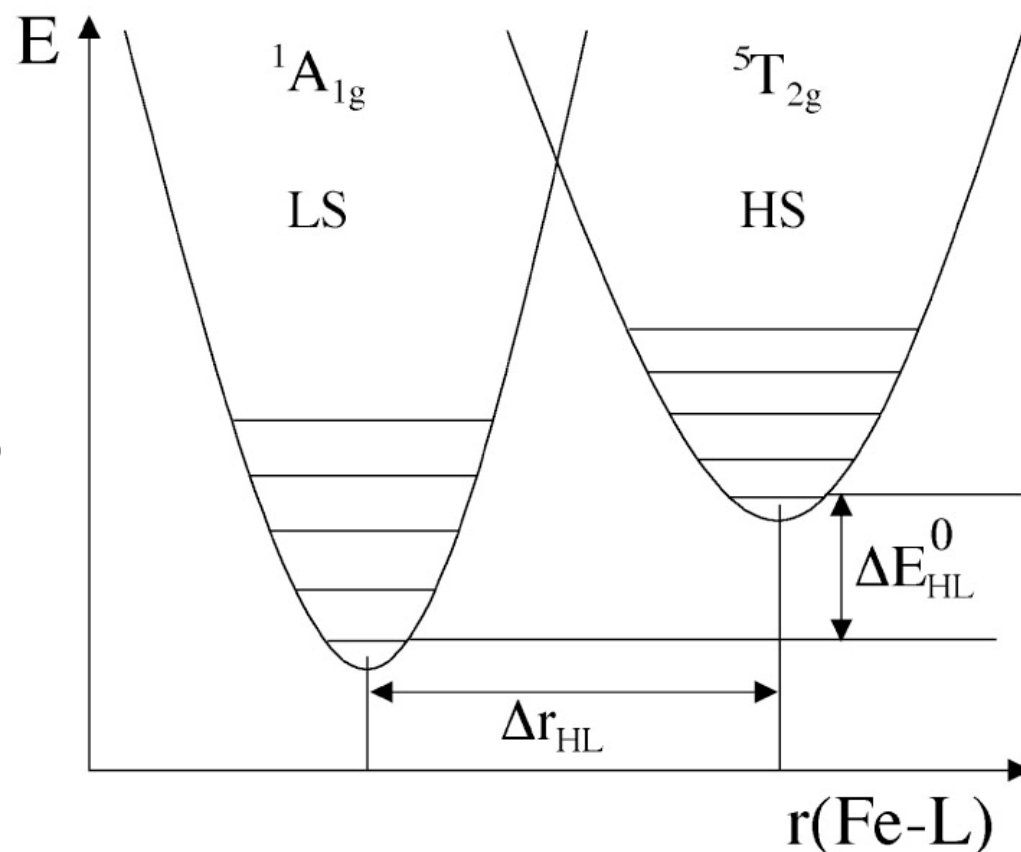
The pronounced structural and optical changes make SCO materials appealing for practical applications



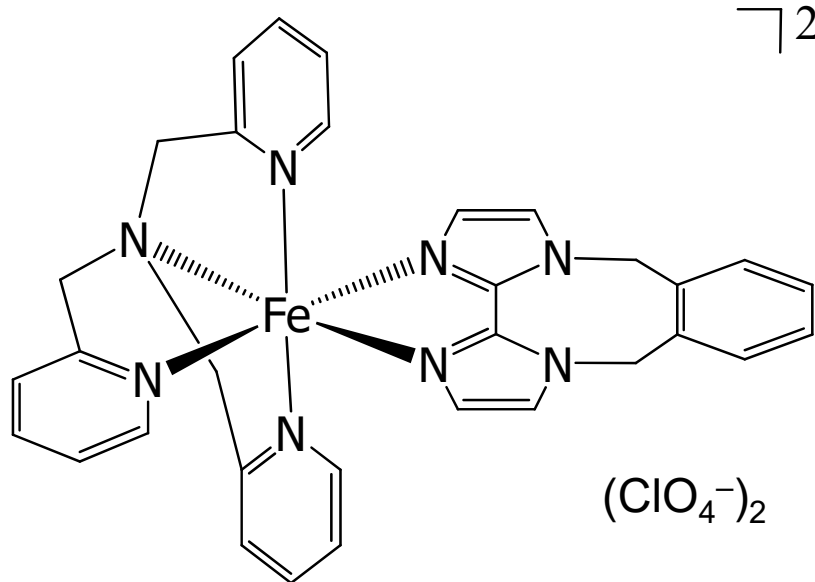
LS, $S = 0$



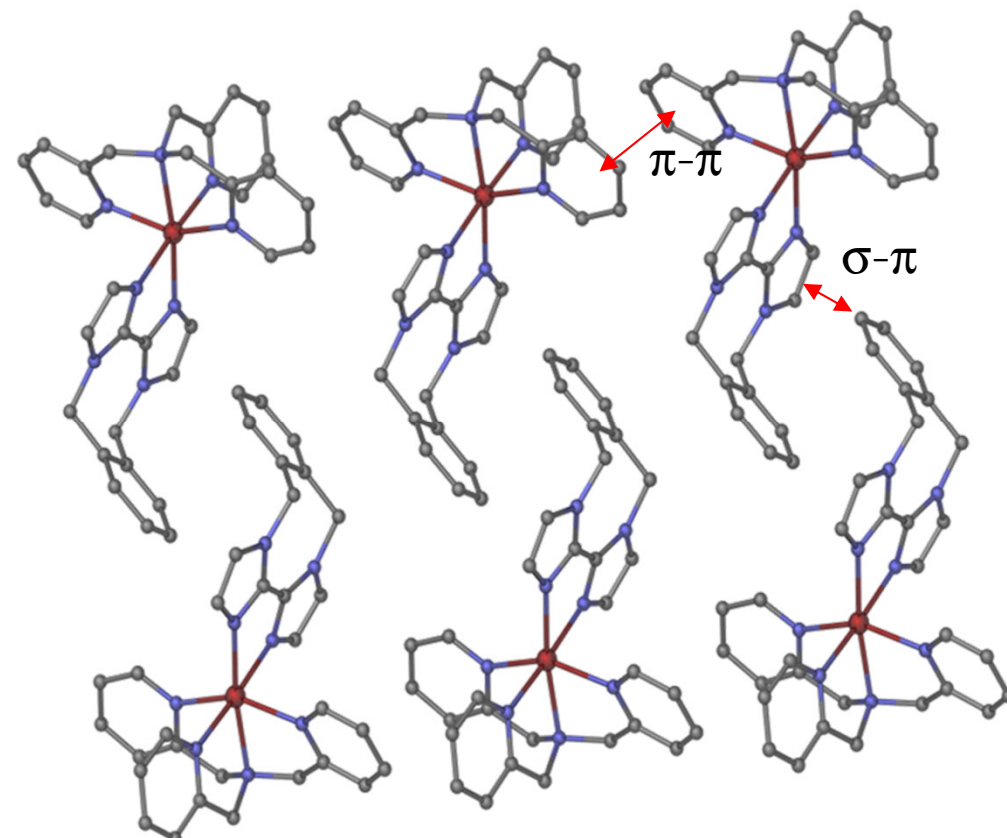
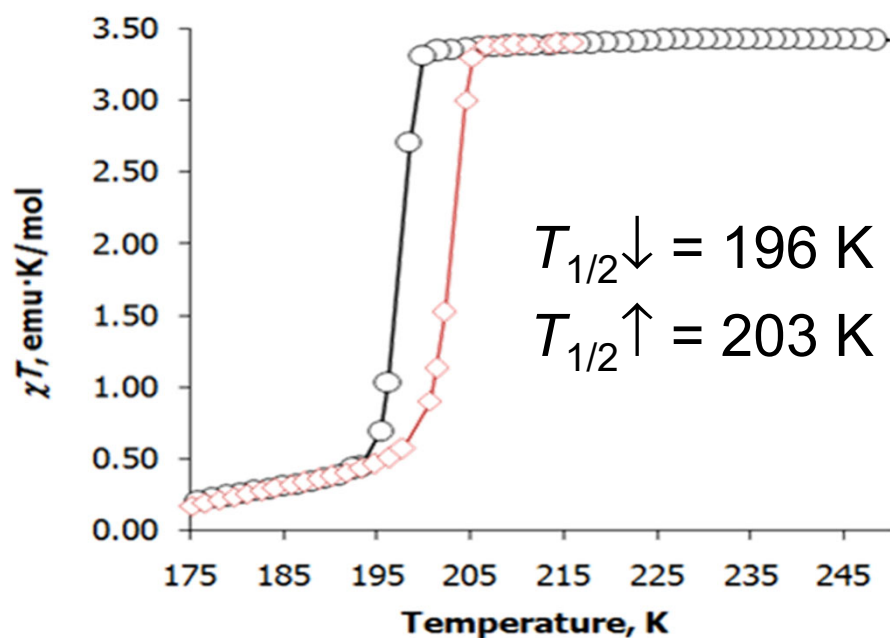
HS, $S = 2$



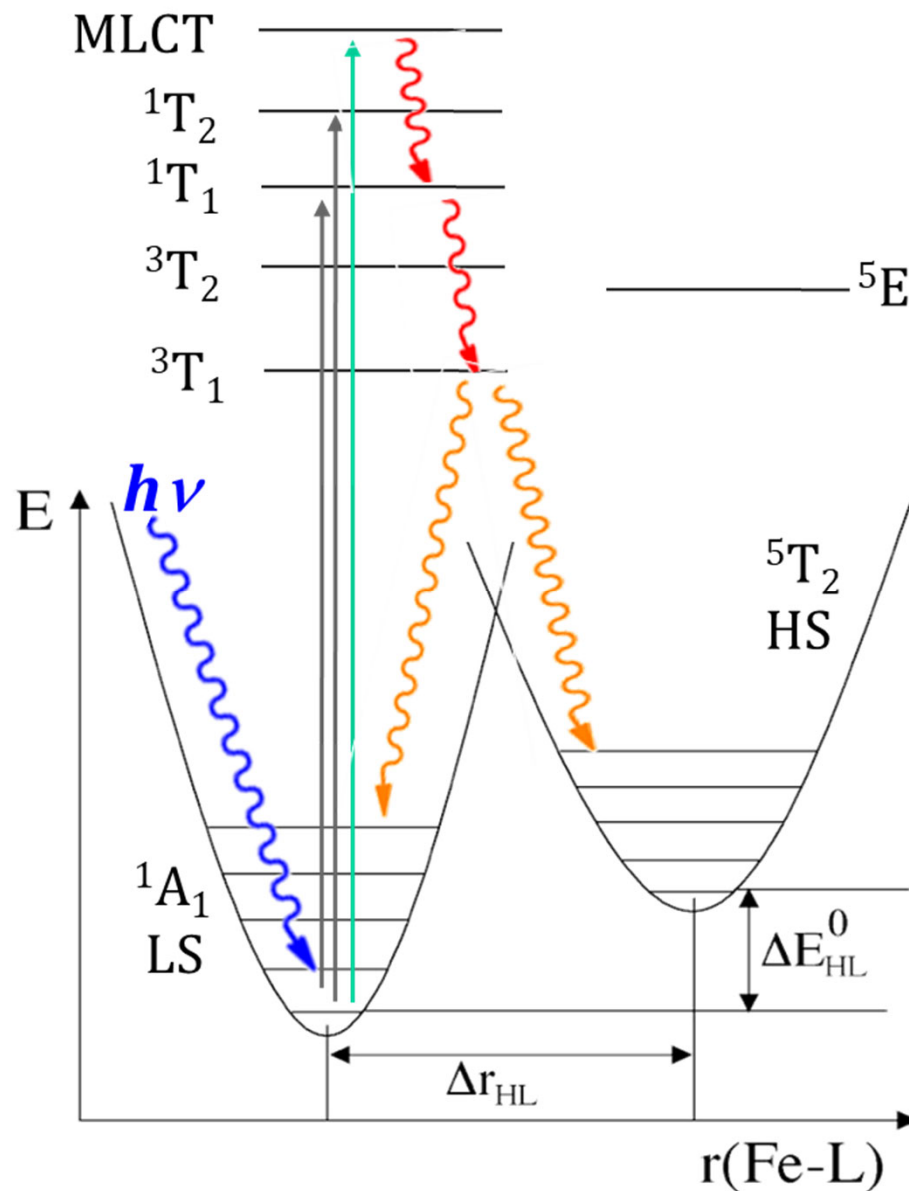
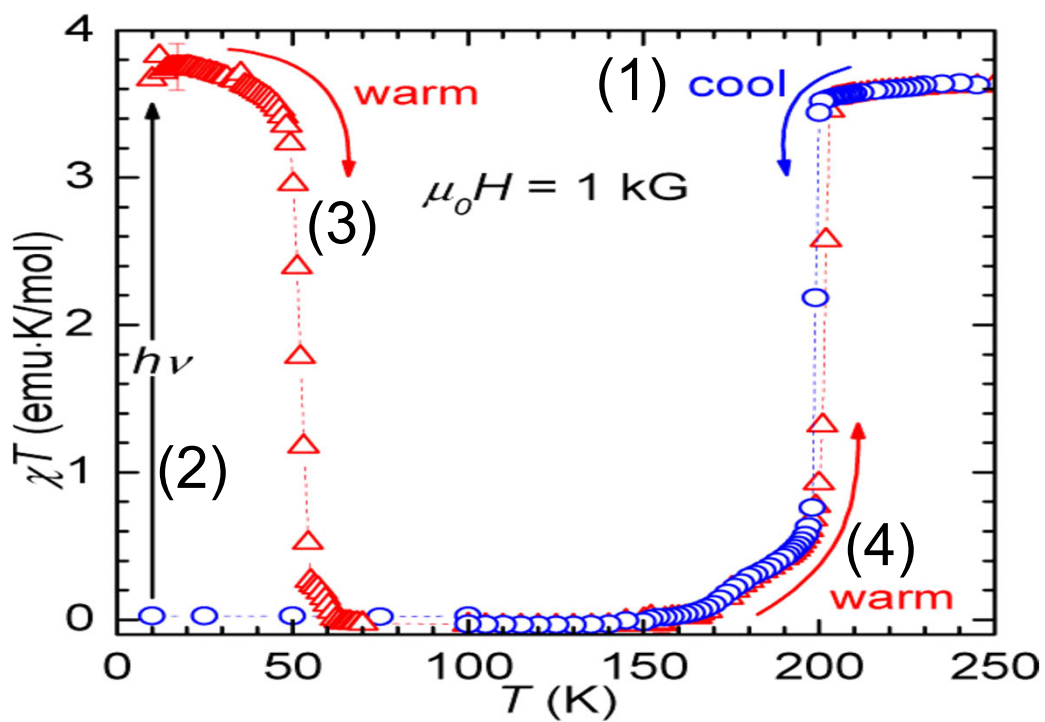
Spin Crossover: Example



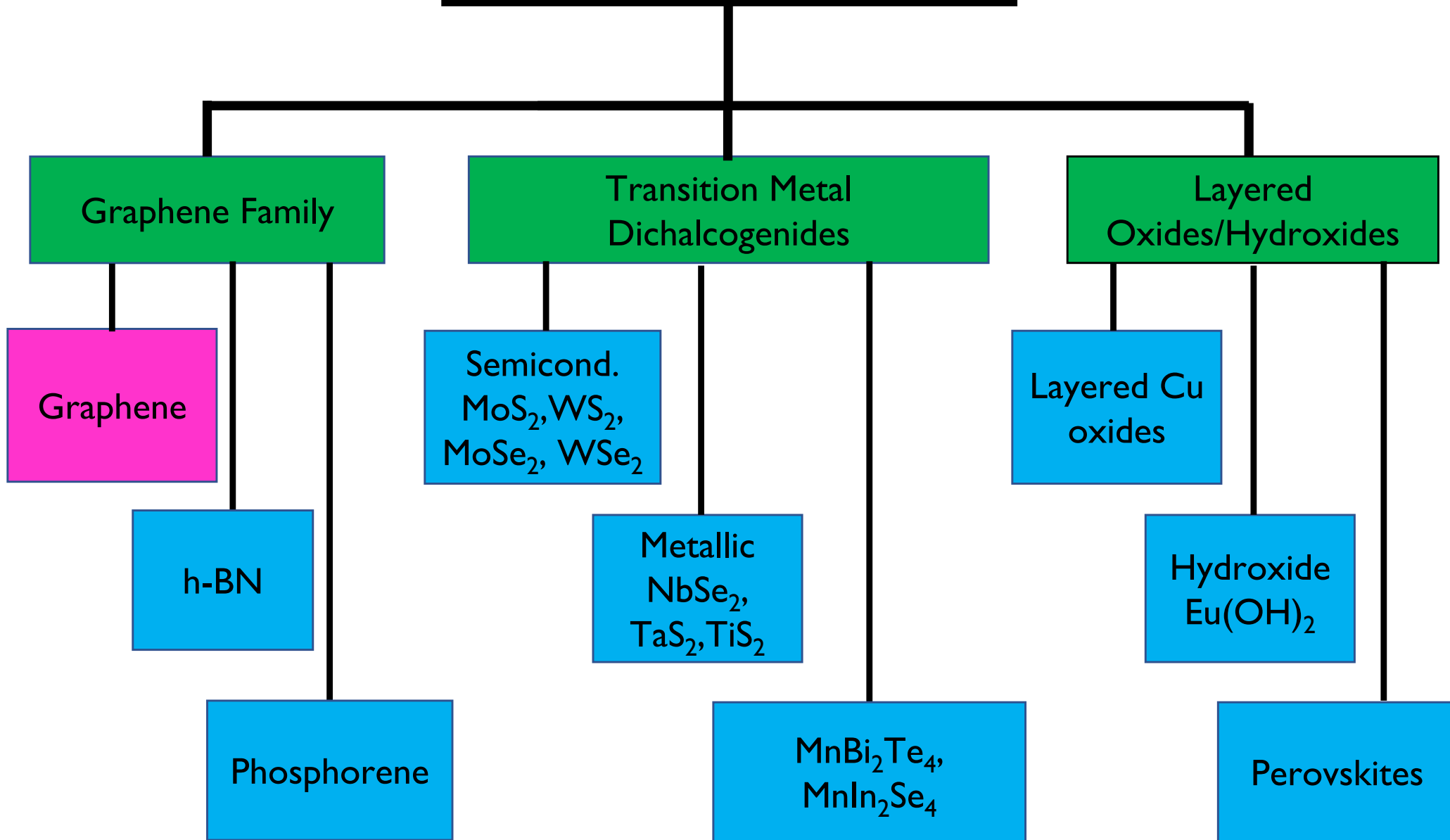
d(Fe-N) _{av} , Å	
123 K (LS)	210 K (HS)
2.002(4)	2.184(4)



Multi-Channel Switching



2D Materials



I. Thin Films of SCO Materials

[Fe(H₂Bpz₂)₂(L₂)] (L₂ = bpy, phen)

- Substrates: Si, glass, ITO-coated glass, polymer tape

- Thickness: 400-500 nm

- $T_{1/2}$ similar to bulk

- Visible color change

- SCO more gradual

- LIESST effect
(saturated in ~5 min)

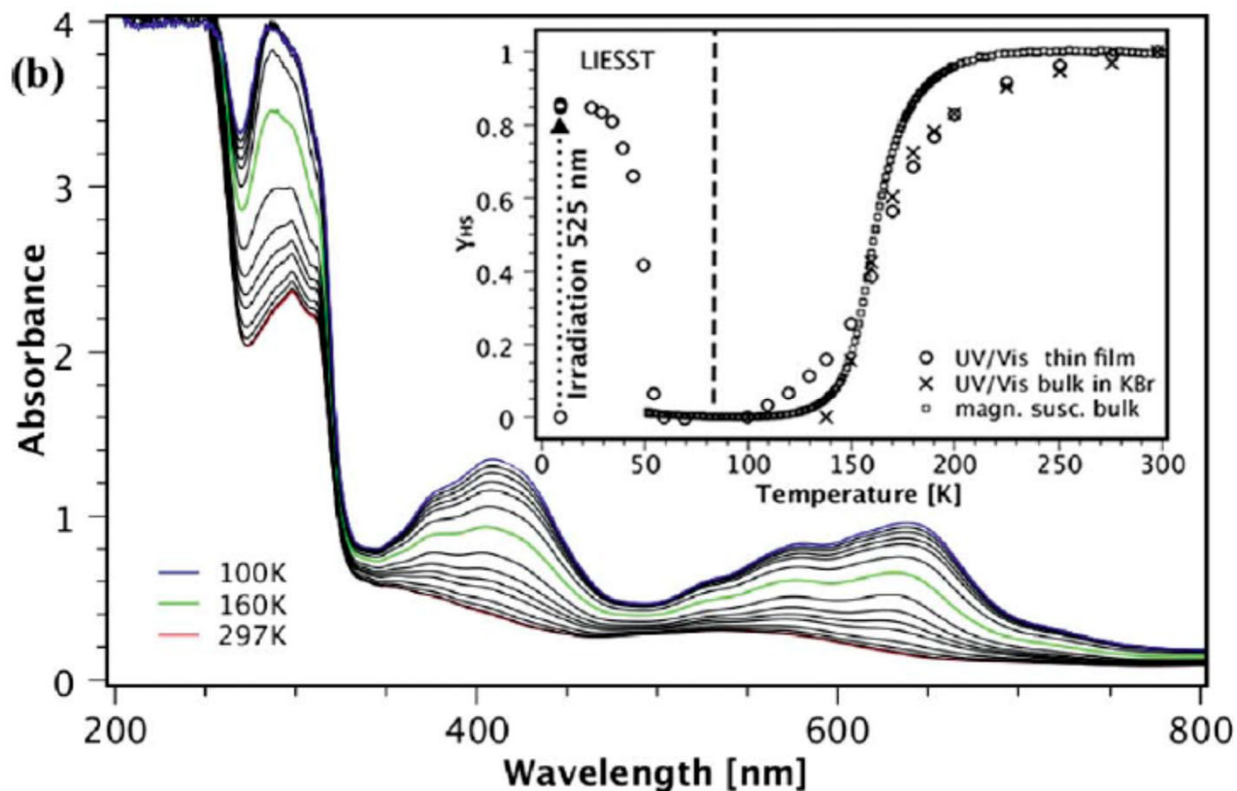
Methods:

- UV-Vis spectroscopy

- DFT calculations

Vacuum deposition

(10⁻² mbar, 160-190 °C)



I. Thin Films of SCO Materials

[Fe(H₂Bpz₂)₂(bpy)] on Au(111)

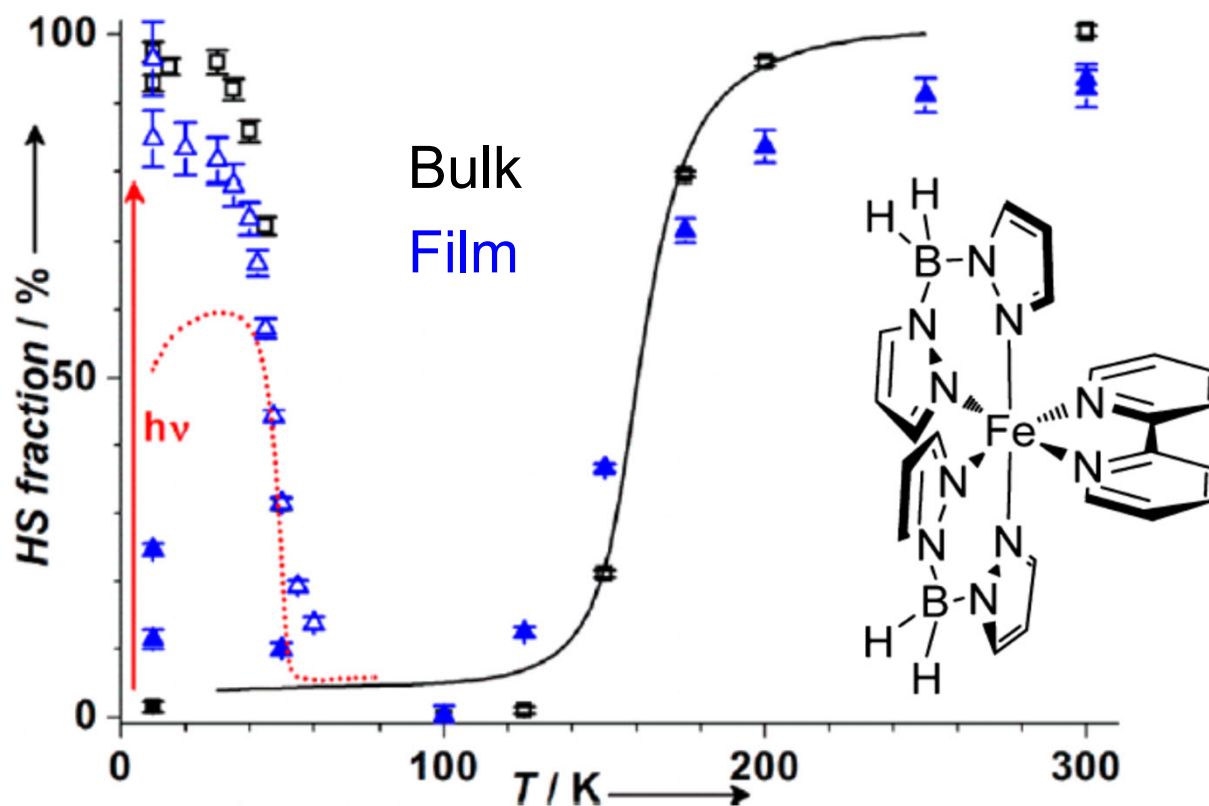
- Thickness: 300 nm
- T_{1/2} similar to bulk
- SCO more gradual
- LIESST effect

Methods:

- UV-Vis, X-ray spectroscopies

Vacuum deposition
(10⁻⁶ mbar, 130 °C)

XAS quantification



I. Thin Films of SCO Materials

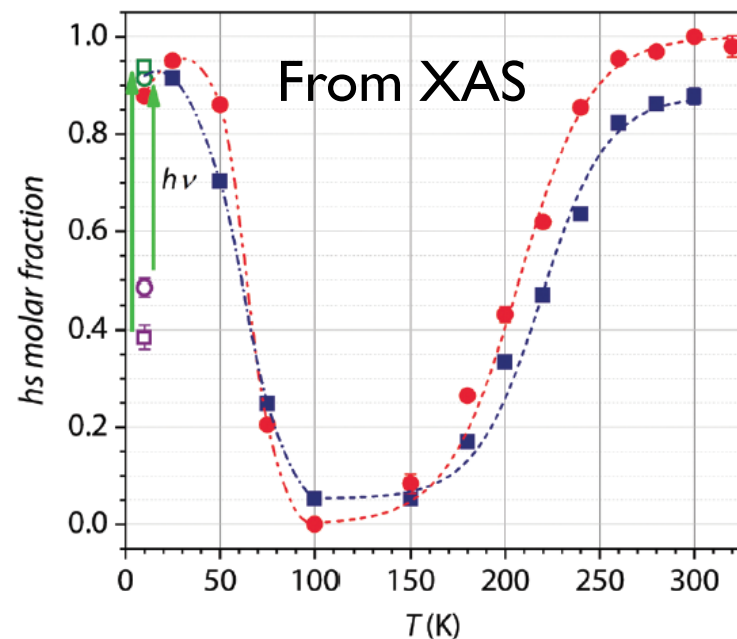
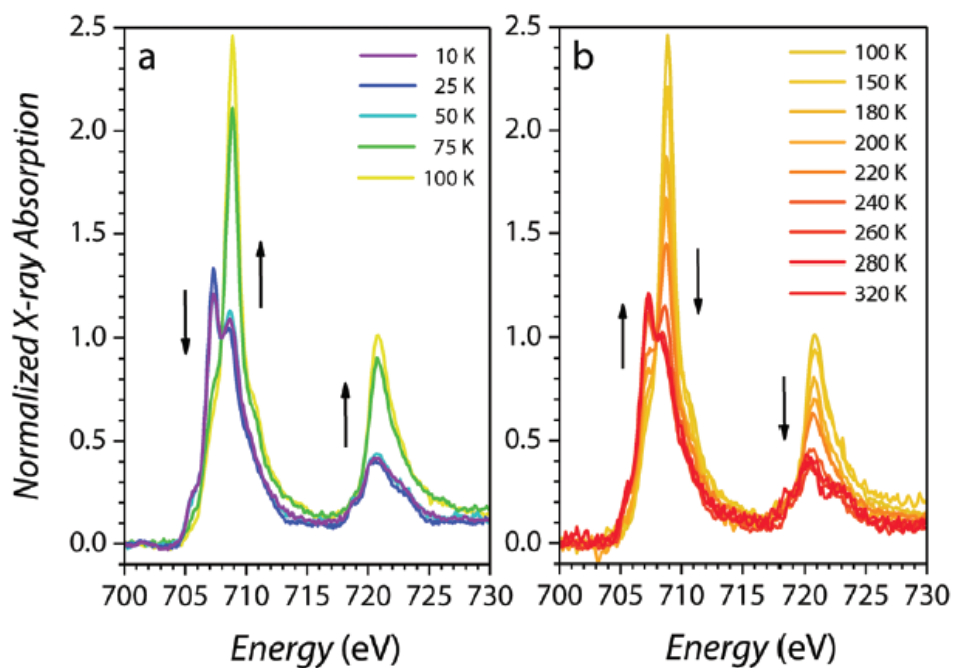
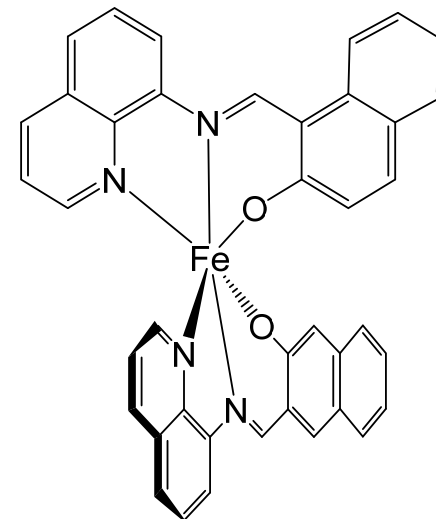
[Fe(qnal)₂ on Au(111)]

- Thickness: 50 nm
- $T_{1/2}$ similar to bulk
- SCO more gradual
- LIESST, SOXIESST

Vacuum deposition
(10^{-8} mbar, 350 °C)

Methods:

- UV-Vis, XAS



II. Ultrathin Films of SCO Materials

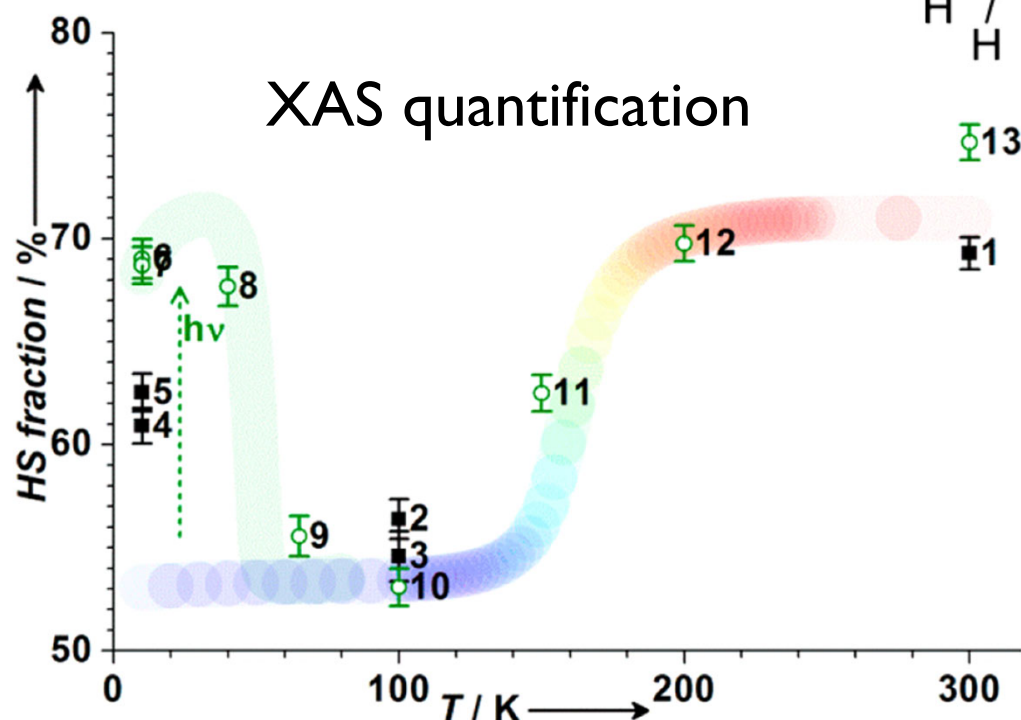
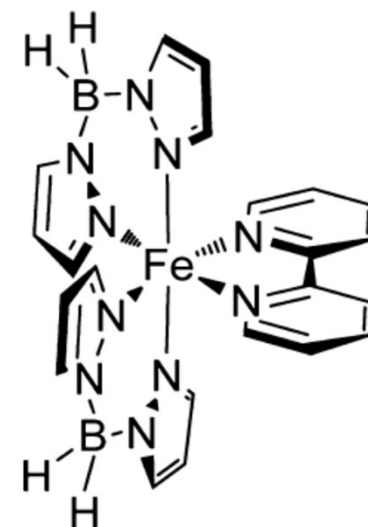
[Fe(H₂Bpz₂)₂(bpy)] on Au(111)

- Submonolayers (0.03-0.14 ML)
- ≈20% showed SCO, 53% HS-, 27% LS-pinned
- SCO more gradual
- LIESST, SOXIESST

Vacuum deposition (10⁻⁶ mbar, 130 °C)

Methods:

- UV-Vis, XAS



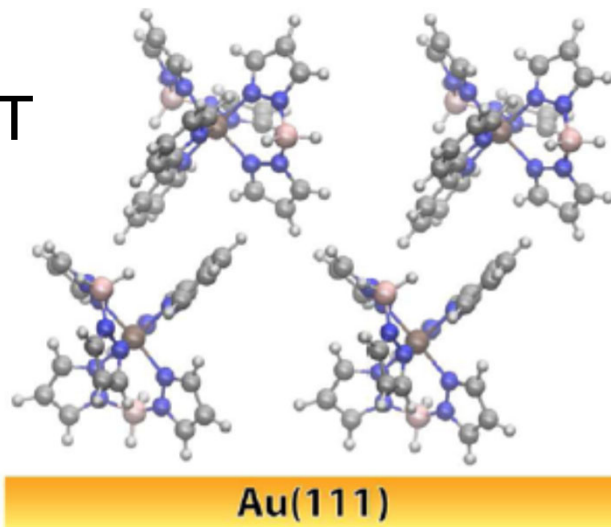
II. Ultrathin SCO Films

$[\text{Fe}(\text{H}_2\text{Bpz}_2)_2(\text{bpy})]$ on Au(111)

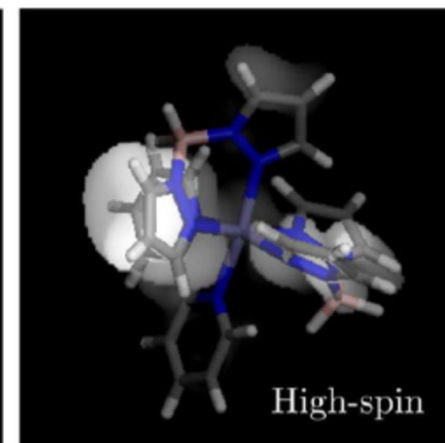
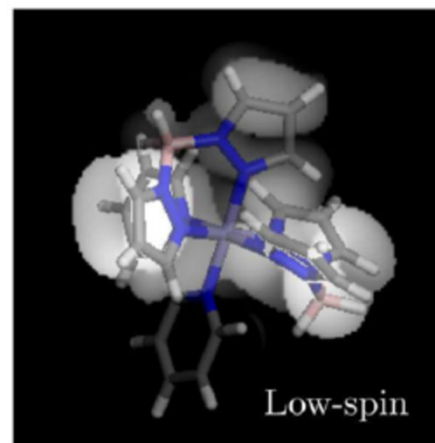
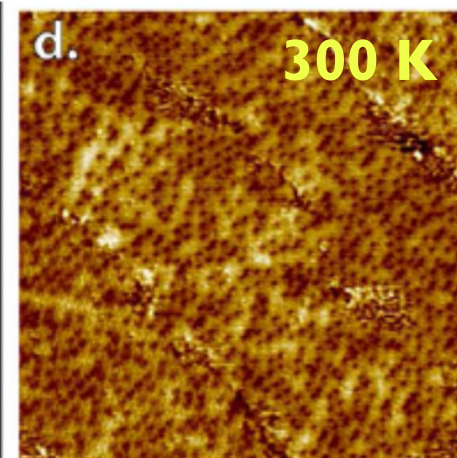
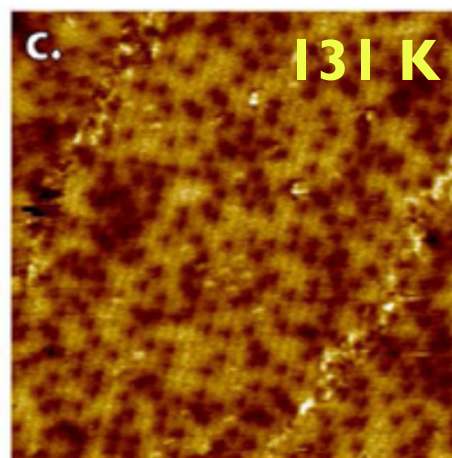
- A bilayer film
- HS and LS states co-exist (1:1) in the 131–300 K range
- Temperature-independent
- HS: smaller transport gap

Methods:

- STM, DFT



Conductance



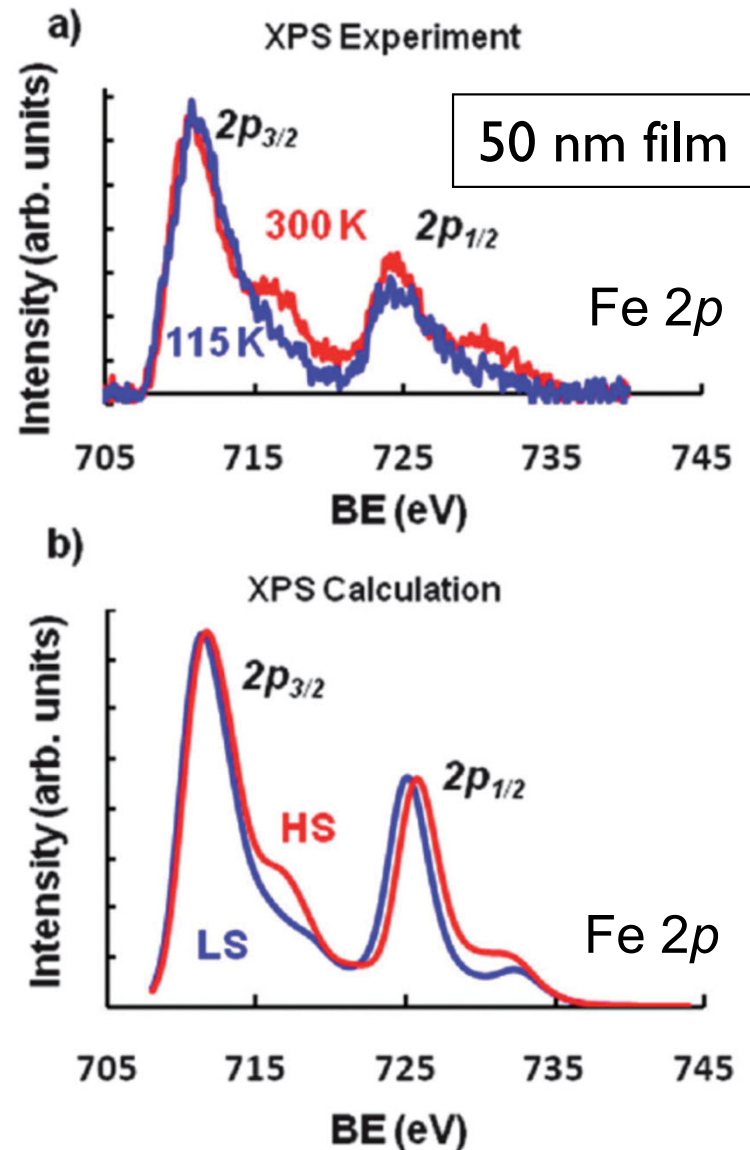
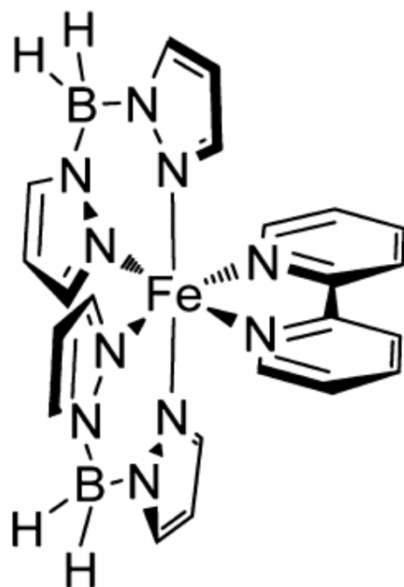
II. Ultrathin SCO Films

[Fe(H₂Bpz₂)₂(bpy)] on Au(111)

- Well-ordered bilayer
- Loss of order in the 3rd layer
- 50 nm film: grainy structure but SCO observed by XPS →

Methods:

- STM, XPS, UPS, DFT



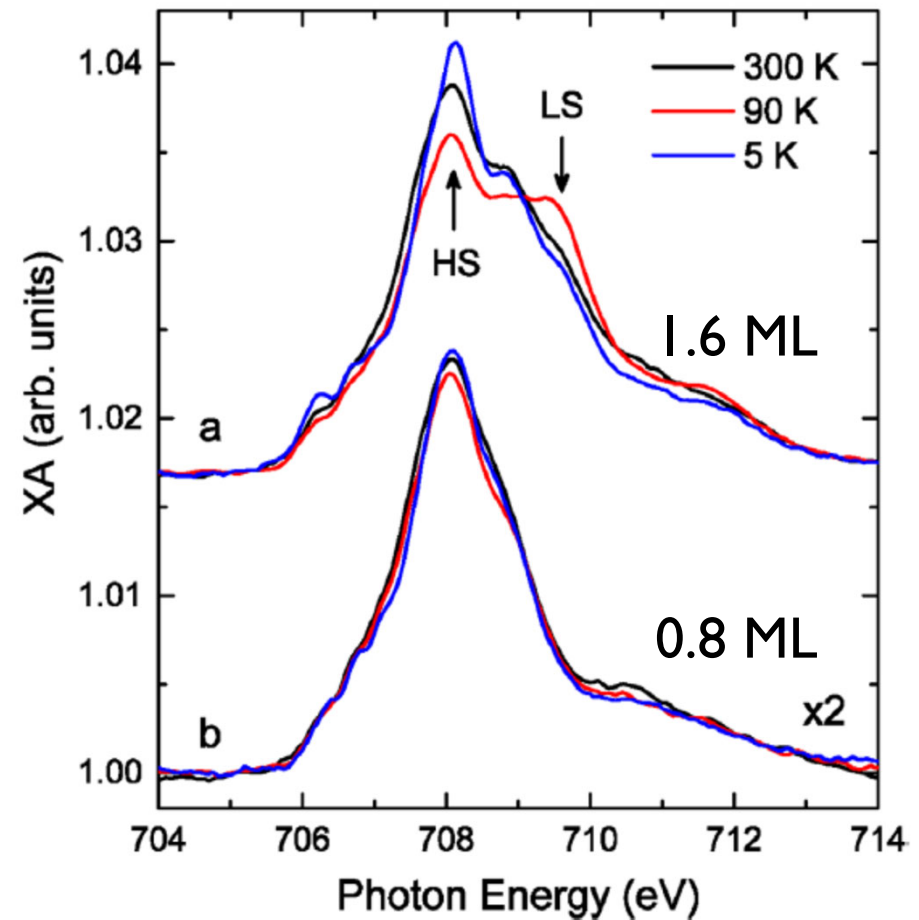
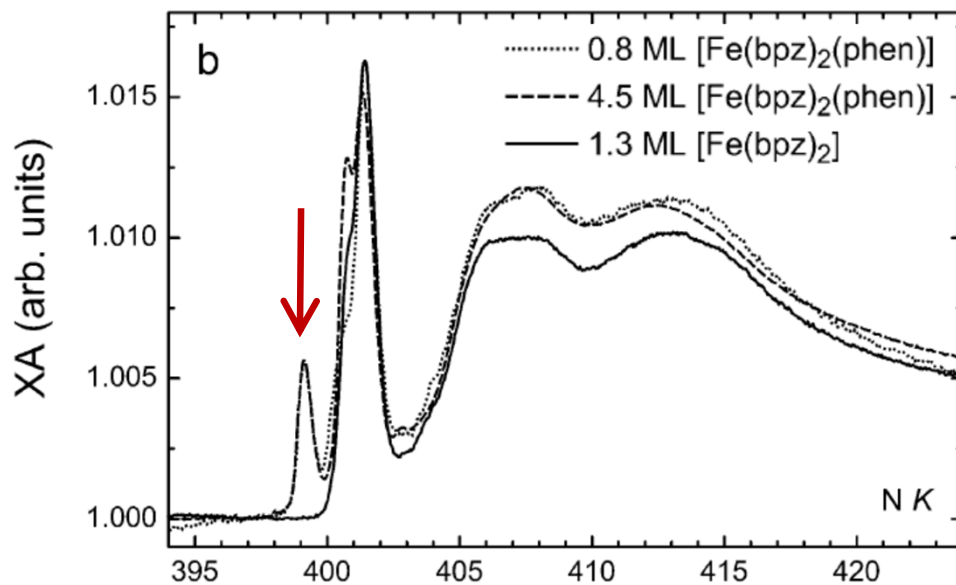
II. Ultrathin SCO Films

[Fe(H₂Bpz₂)₂(phen)] on Au(111)

- Sub-monolayer: decomposition to [Fe(H₂Bpz₂)₂] (loss of ligand!)
- Only the 2nd layer shows SCO

Methods:

- STM, NEXAFS

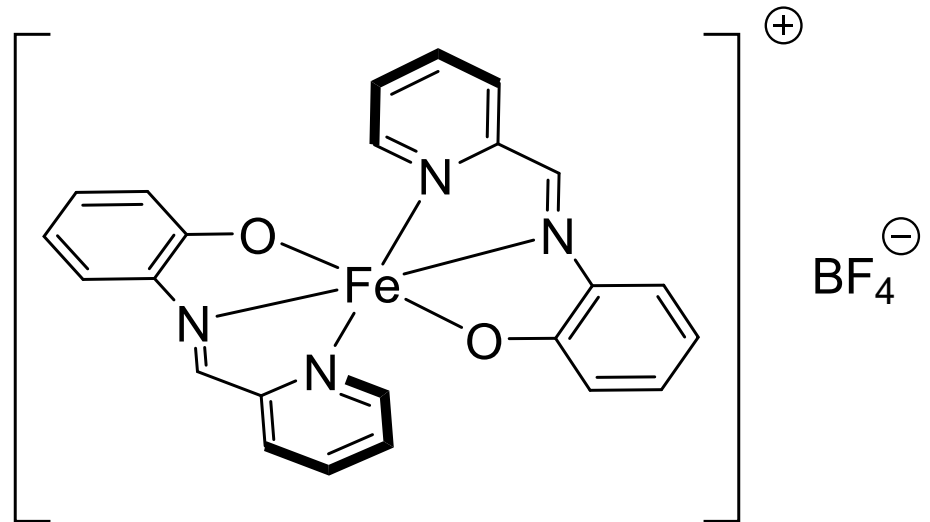


II. Ultrathin SCO Films

$[\text{Fe}(\text{pap})_2](\text{BF}_4)_2$ on $\text{Cu}_2\text{N}/\text{Cu}(100)$

- First example of deposition for a charged SCO complex

Vacuum deposition
(10^{-9} mbar, 350°C)



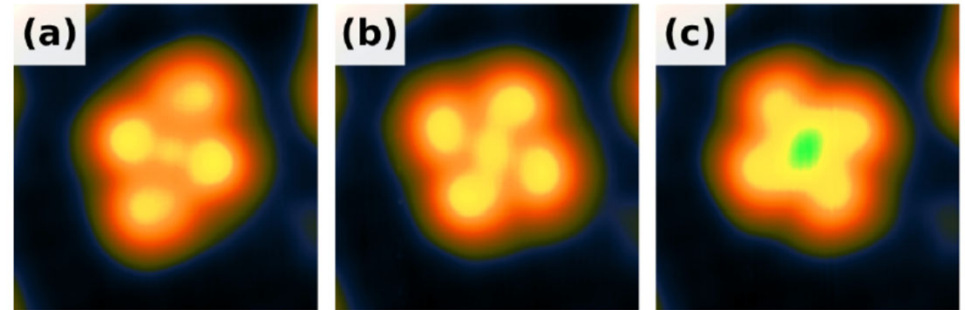
We would like to stress that since the charge state of the adsorbed molecules cannot be unambiguously determined from our data (see below), they are henceforth referred to as $\text{Fe}(\text{pap})_2$, that is, without specifying their charge.

We speculate that the counterions are still present at the surface but are attached to the more reactive Cu trenches. They do not affect the measurements of single $\text{Fe}(\text{pap})_2$ molecules on Cu_2N islands.

II. Ultrathin SCO Films

[Fe(pap)₂](BF₄)₂ on Cu₂N/Cu(100)

- First example of deposition for a charged SCO complex
- Switching between 3 states
- Switching achieved >1.8 V

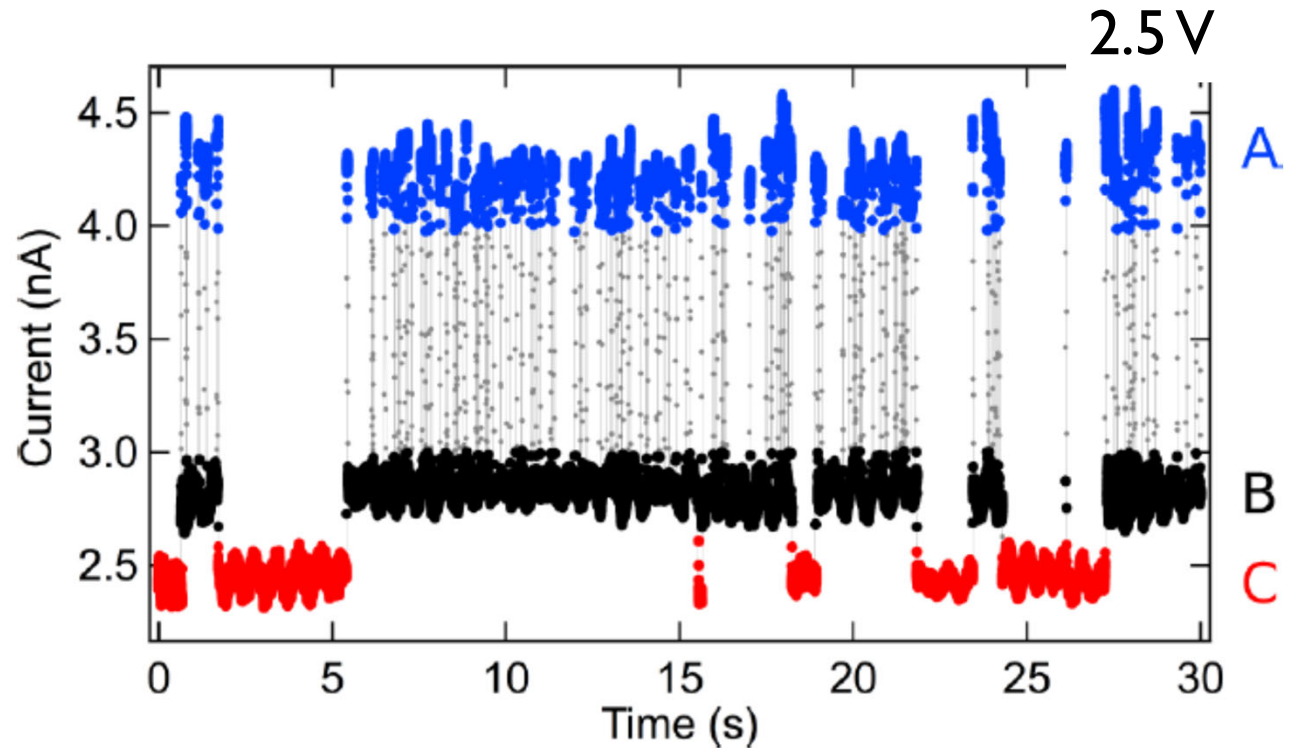


Methods:

- STM, DFT

A lot of Qs:

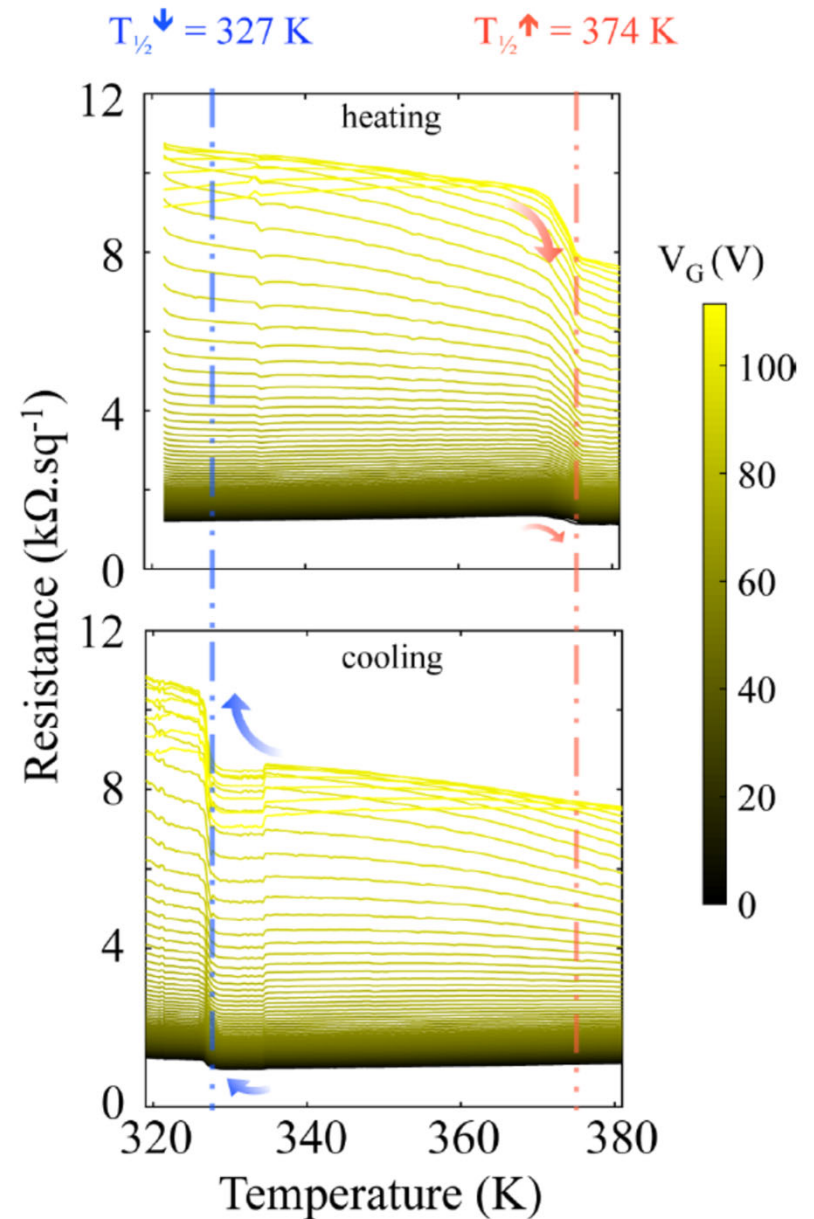
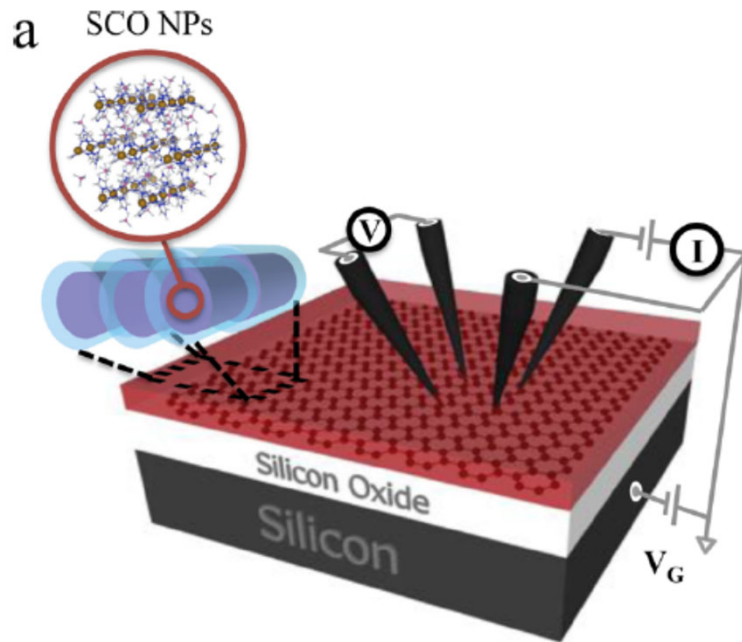
- what are 3 states?
- what is resting state?
- what would be observed w/ [Fe(pap)₂]



II. Ultrathin SCO Films

SCO nanoparticles on graphene

- Deposited by contact printing from the surface of an ethyleneglycol droplet
- Nanorods: $l \sim 25$ nm, $d \sim 9$ nm



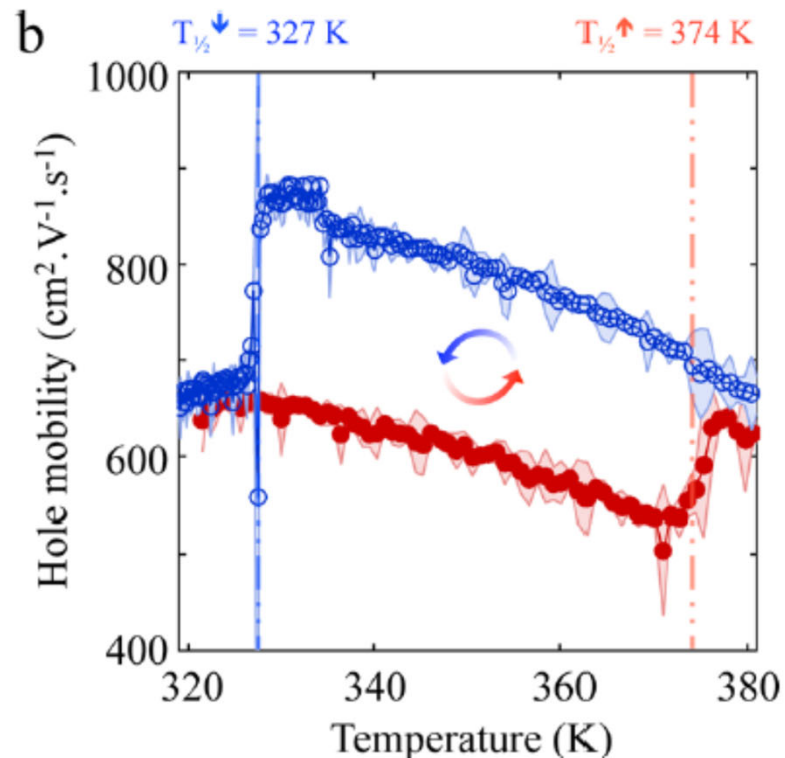
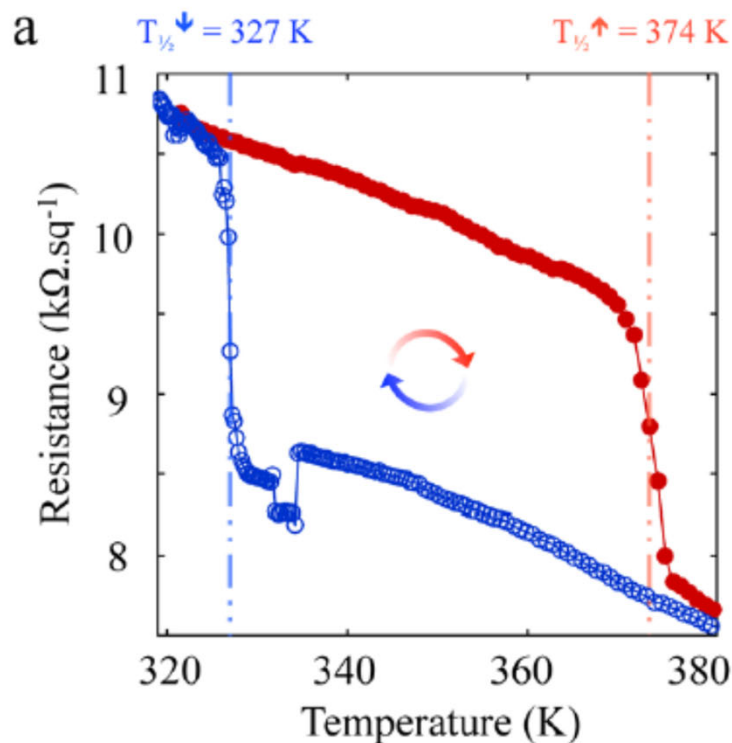
II. Ultrathin SCO Films

SCO nanoparticles on graphene

- The SCO switching behavior reproduces what is observed for the bulk material and is coupled to graphene's transport

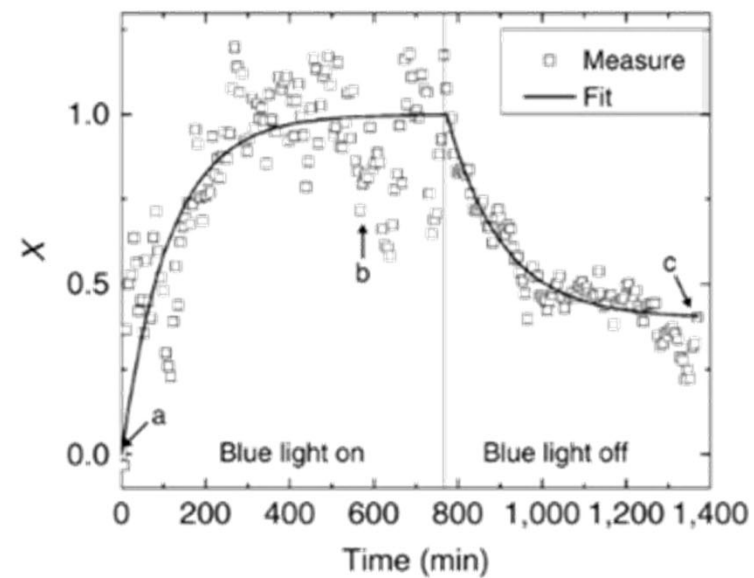
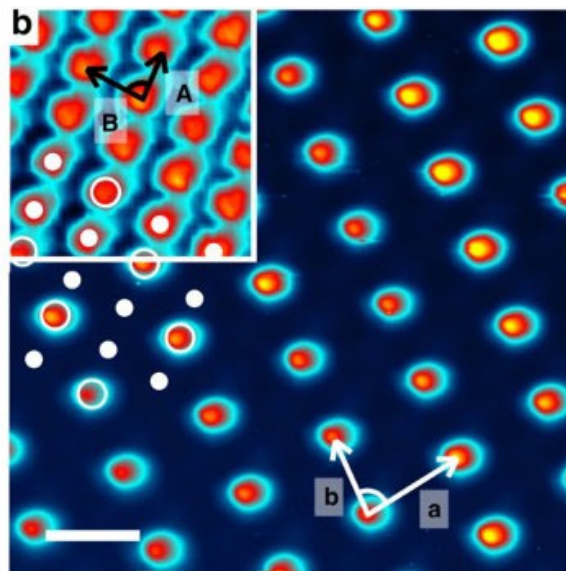
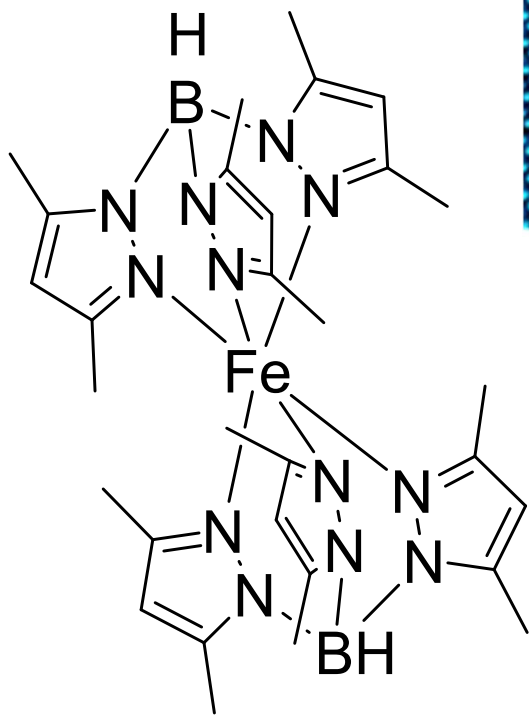
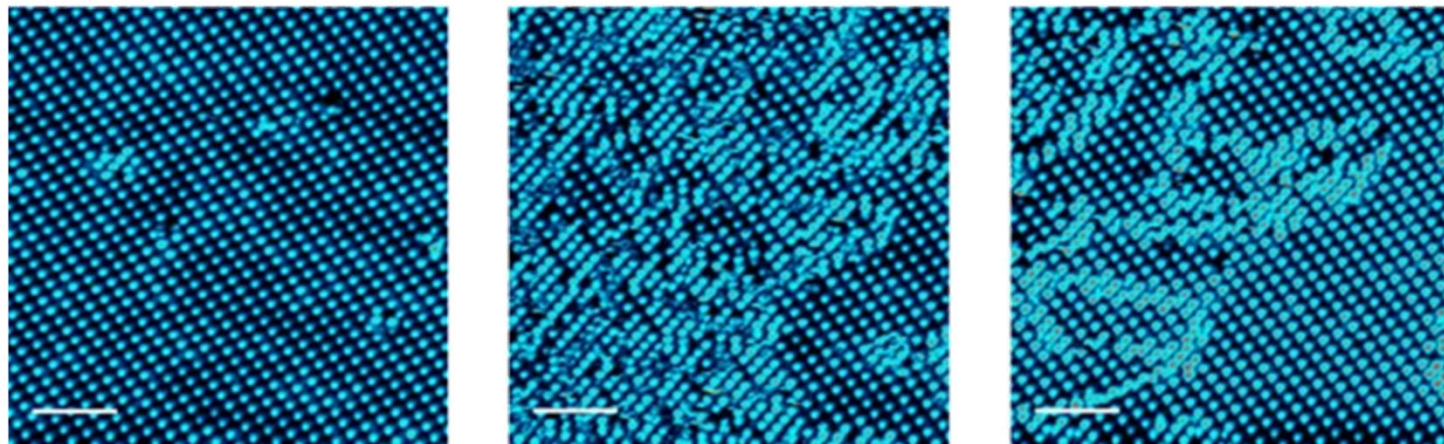
What's the mechanism?

- The Dirac voltage doesn't change
- The coupling is likely structural and not of charge-transfer type
- Hypothesis: dielectric switching



II. Ultrathin SCO Films

Vacuum deposition; (10^{-10} mbar, 320 °C)



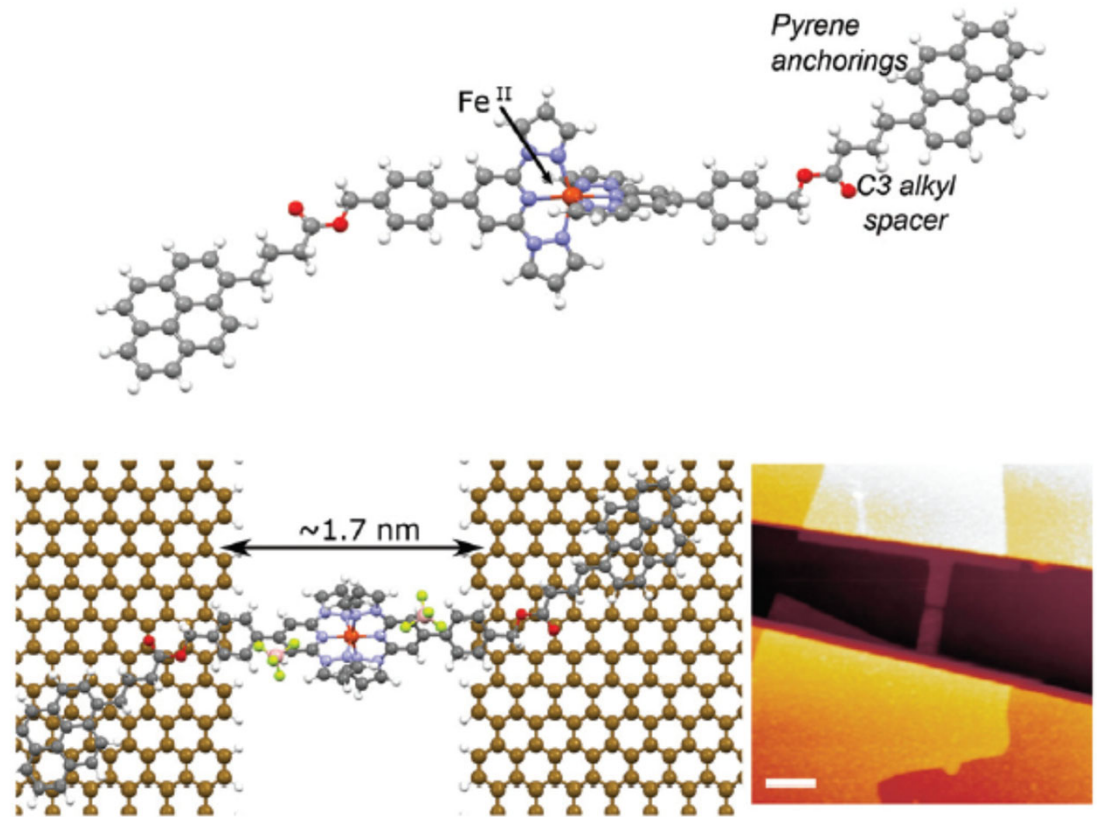
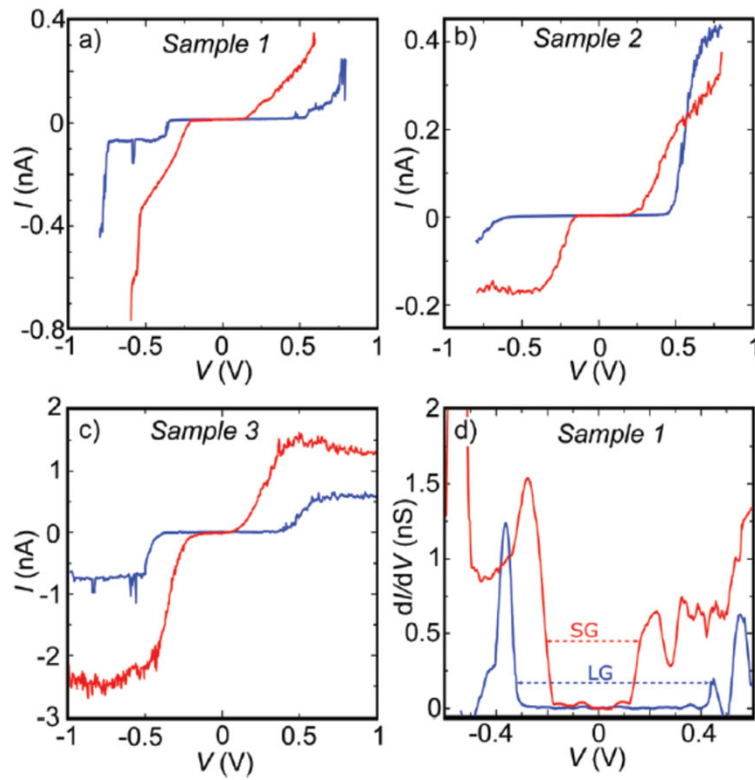
III. Single Molecules

$[\text{Fe}(\text{L})_2]^{2+}$ in a graphene break junction

- Typical electro-burned gap $\sim 1\text{-}2$ nm
- Molecular length ~ 4 nm
- Consistent bistability at 4 K (purely stochastic behavior)

Solution deposition:

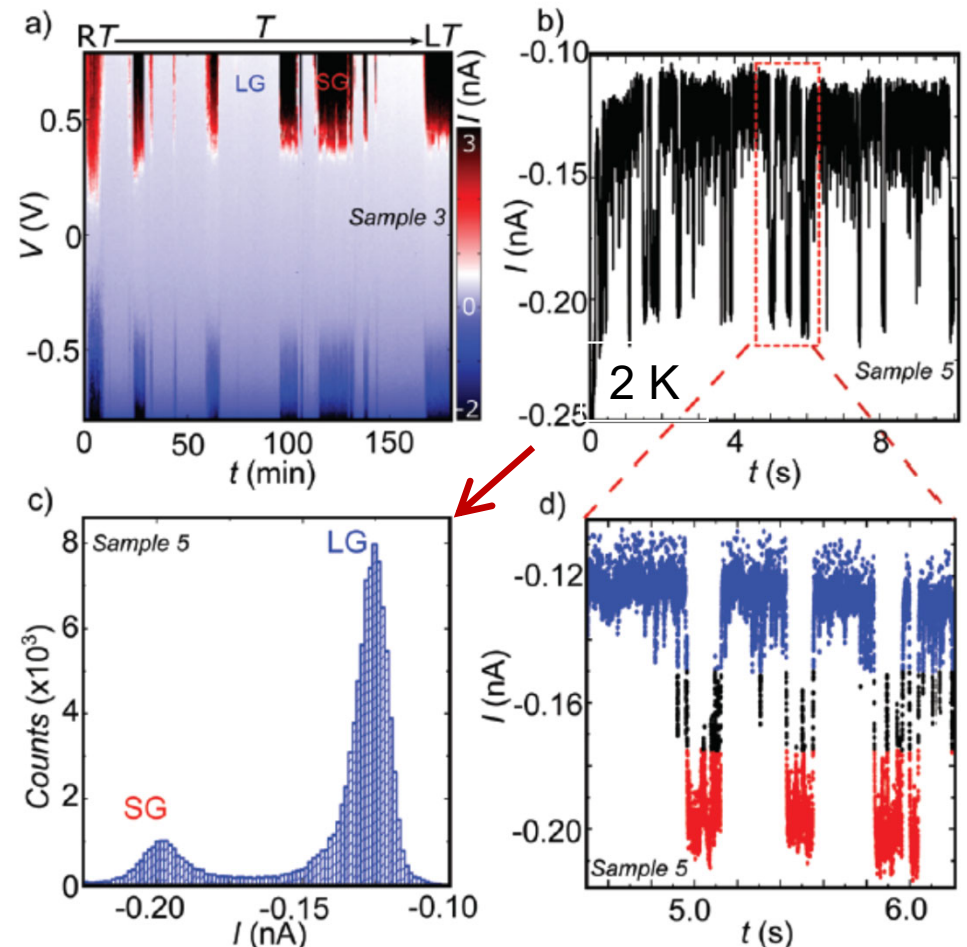
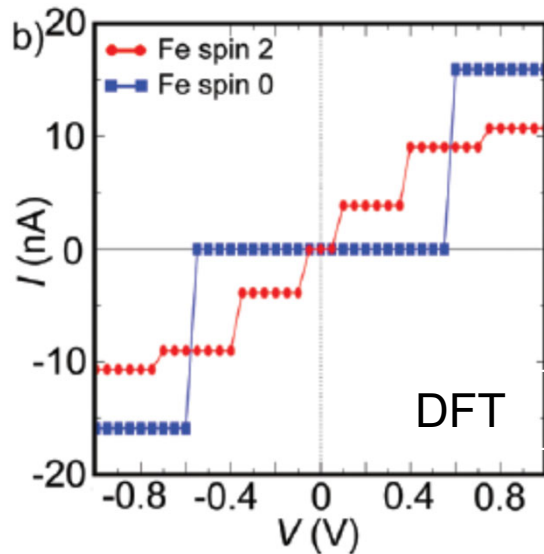
- drop-casting a 10^{-4} M solution in acetonitrile



III. Single Molecules

$[\text{Fe}(\text{L})_2]^{2+}$ in graphene break junction

- The large-gap / small-gap states have been assigned to HS / LS states, respectively
- The switching persists well beyond the SCO temperature observed in the bulk



Outline

- ❖ Spin Crossover: Quick Introduction
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 - Thin films
 - Ultrathin films
 - Single molecules
- ❖ Spin Crossover Films via Gas Phase
- ❖ Spin Crossover Films via Exfoliation



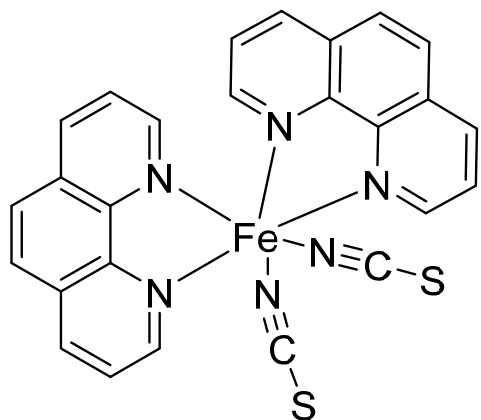
Depositing Molecules on Substrates

Source →	Solution	Gas Phase	Solid
Generality	High	Moderate	Low(?)
Scalability	High	Moderate	Moderate
Purity	Low	High	Moderate
Requirements			
e-neutrality	n/a	✓	○
solubility	✓	n/a	n/a
volatility	n/a	✓	n/a
thermal stability	○	✓	○
surface stability	✓	✓	○

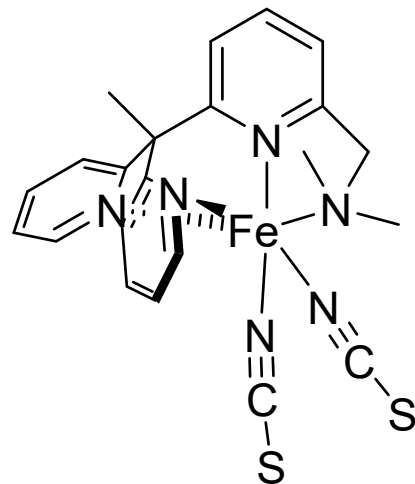
✓ = REQUIRED ○ = DESIRED



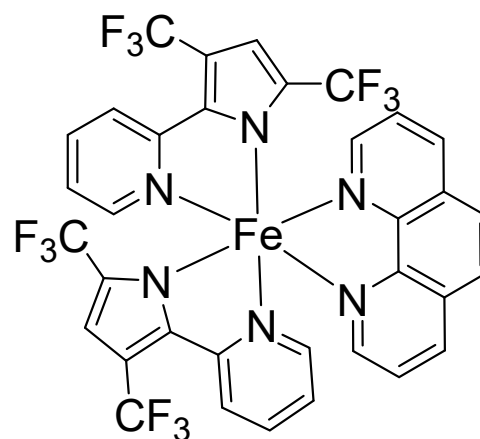
Gas-Phase Deposition of SCO Films



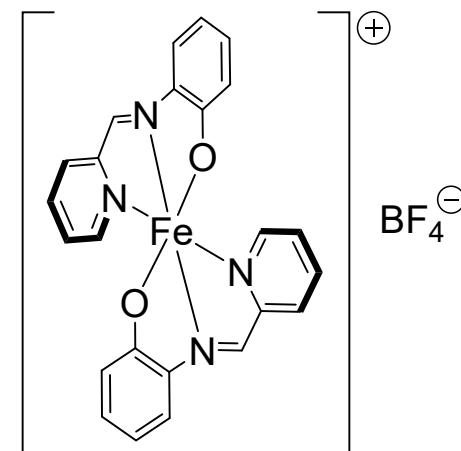
180 °C
10⁻⁸ mbar



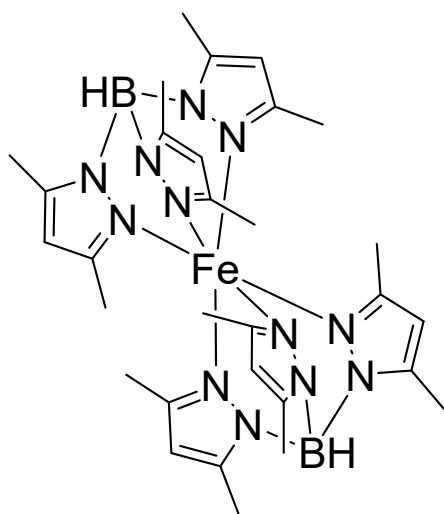
237 °C
10⁻⁹ mbar



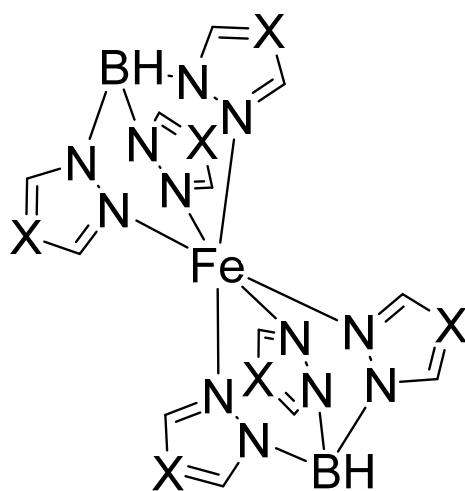
160 °C
10⁻⁹ mbar



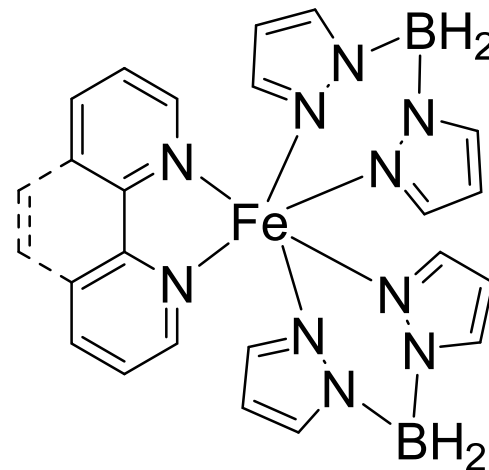
100 °C
10⁻⁹ mbar



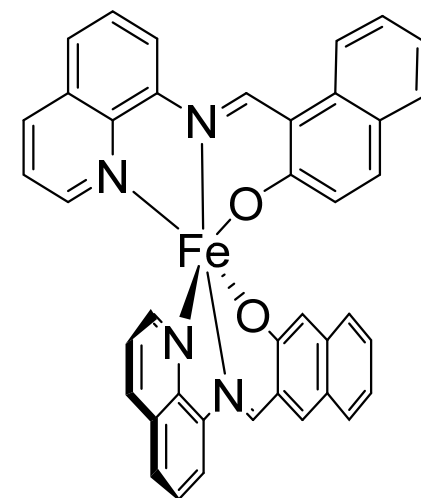
140 °C
10⁻⁸ mbar



190 °C
10⁻⁵ mbar



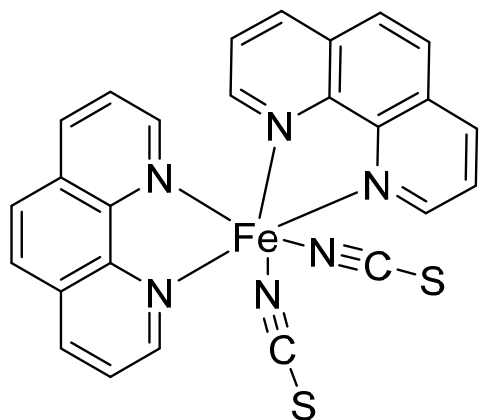
162 °C
10⁻² mbar



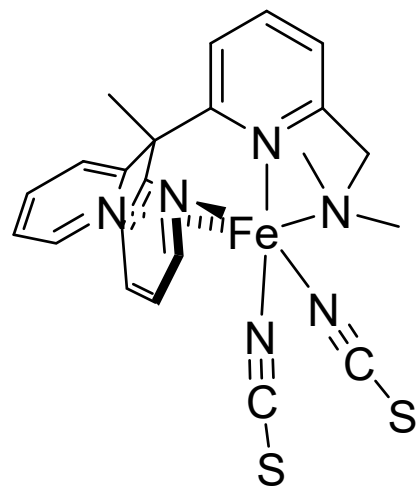
217 °C
10⁻⁹ mbar



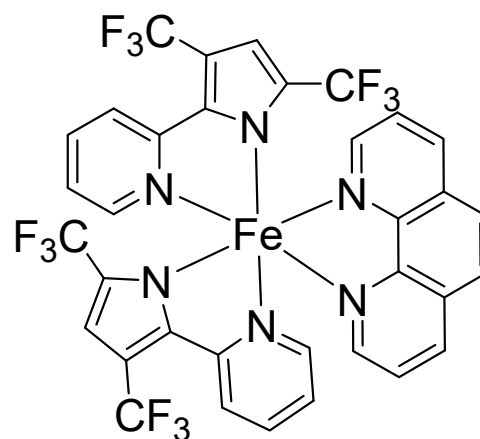
Gas-Phase Deposition of SCO Films



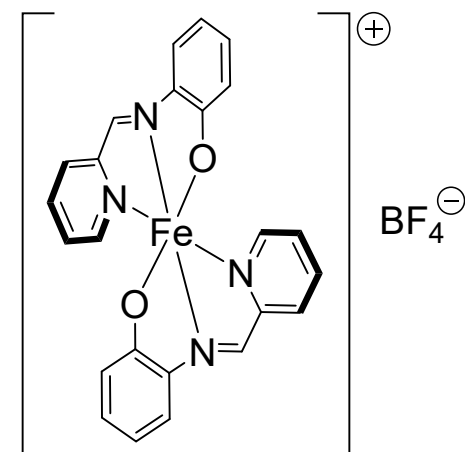
180 °C
10⁻⁸ mbar



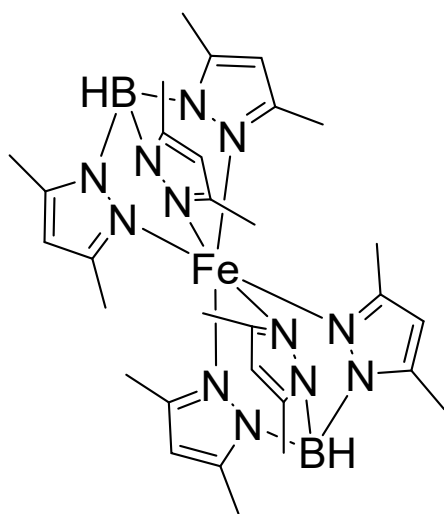
237 °C
10⁻⁹ mbar



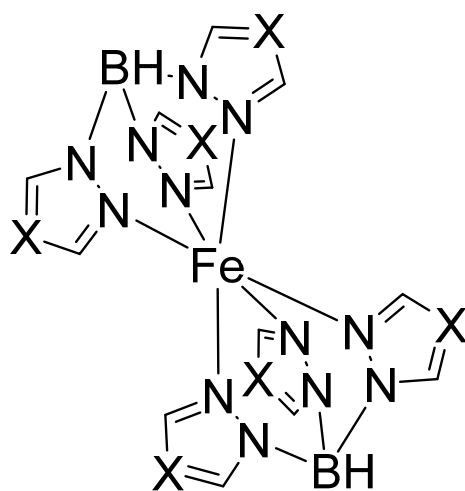
160 °C
10⁻⁹ mbar



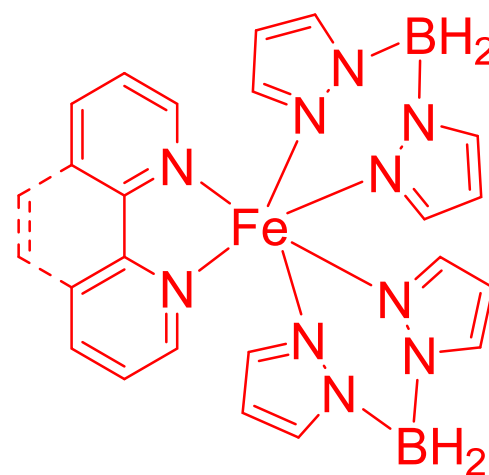
100 °C
10⁻⁹ mbar



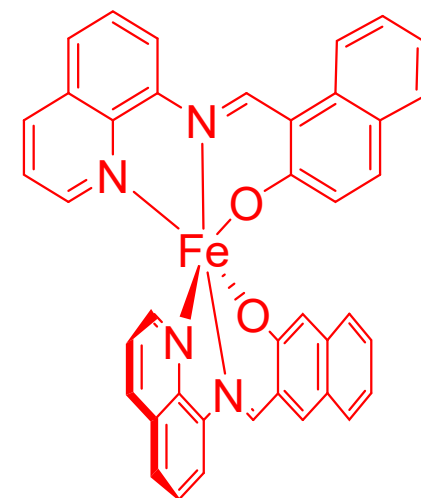
140 °C
10⁻⁸ mbar



190 °C
10⁻⁵ mbar



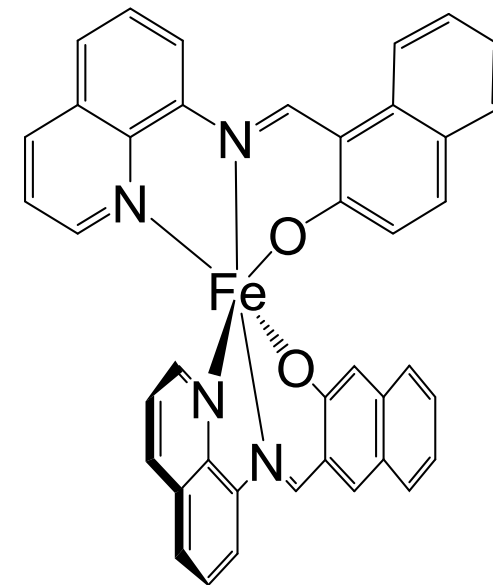
162 °C
10⁻² mbar



217 °C
10⁻⁹ mbar



[Fe(qnal)₂] on Au(III)

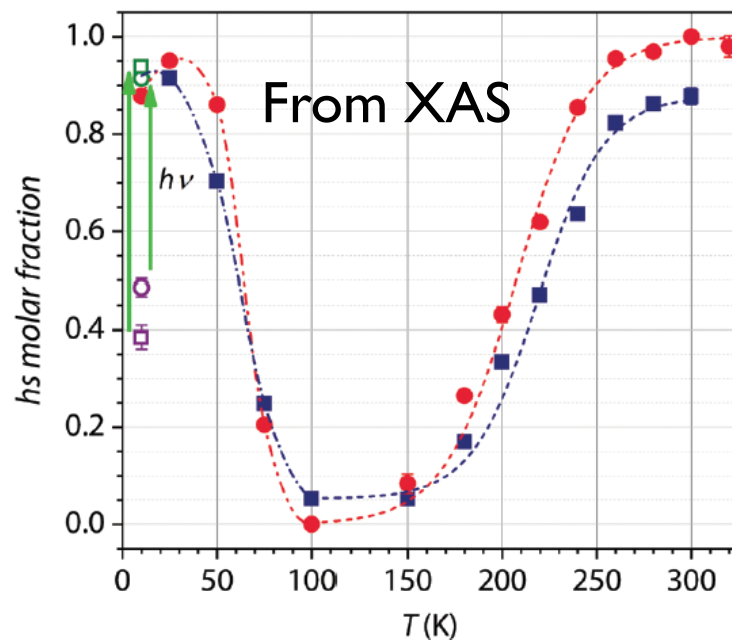
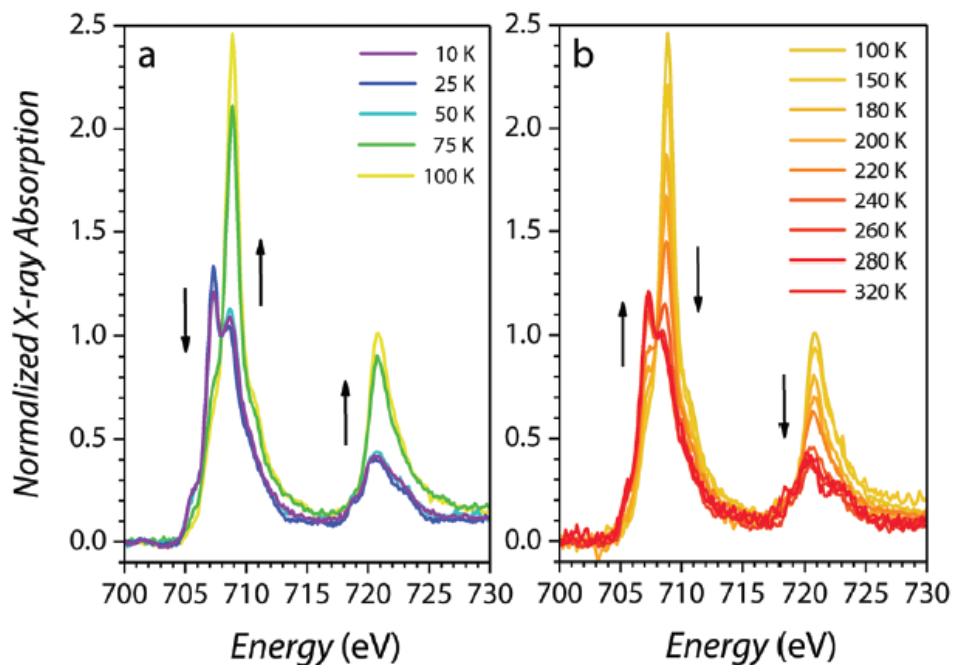


- Thickness: 300 nm
- $T_{1/2}$ similar to bulk
- SCO more gradual
- LIESST effect

Vacuum deposition
(10^{-8} mbar, 350 °C)

Methods:

- UV-Vis, XAS



Molecular Design Challenge

Cooperativity: **strong**
intermolecular interactions

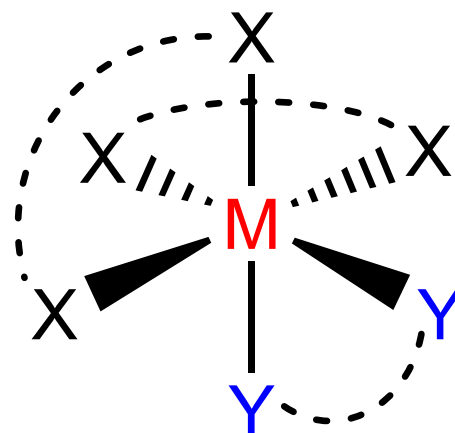
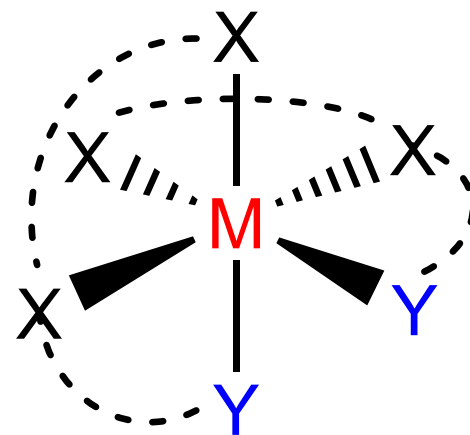
Volatility: **weak**
intermolecular interactions

Challenge: **increase the volatility while preserving the abrupt spin transition**

Solution: **use asymmetric design by separating the cooperative and “volatilizing” functions**

Criteria:

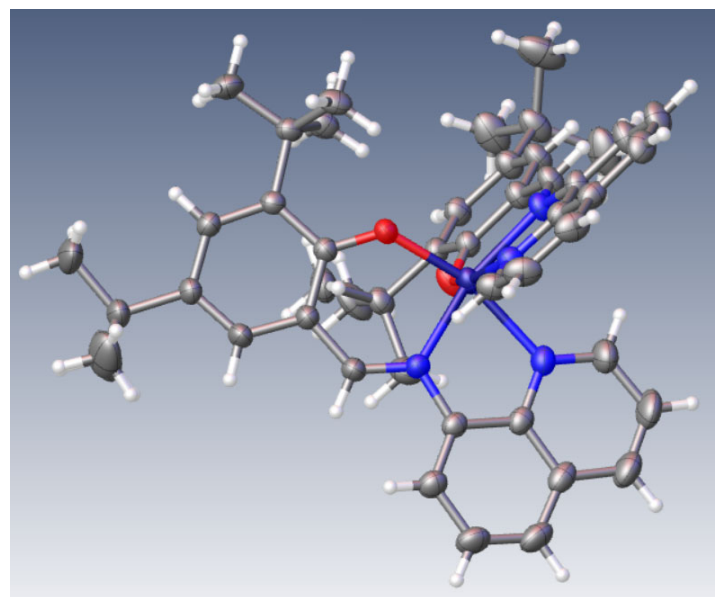
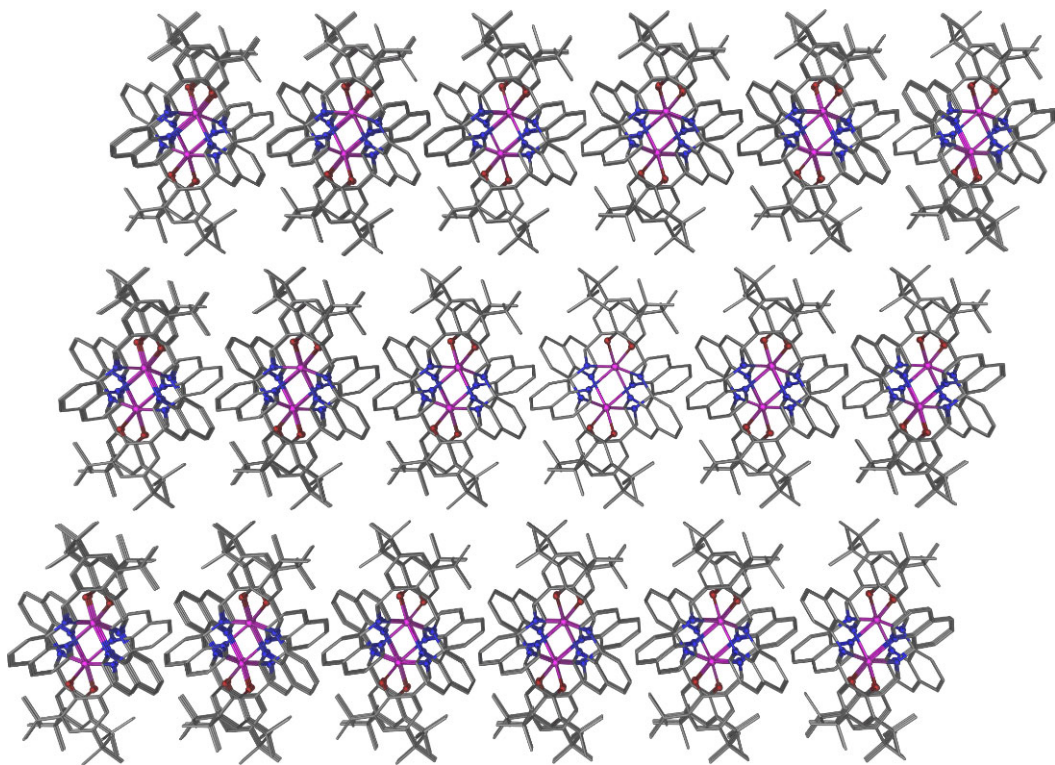
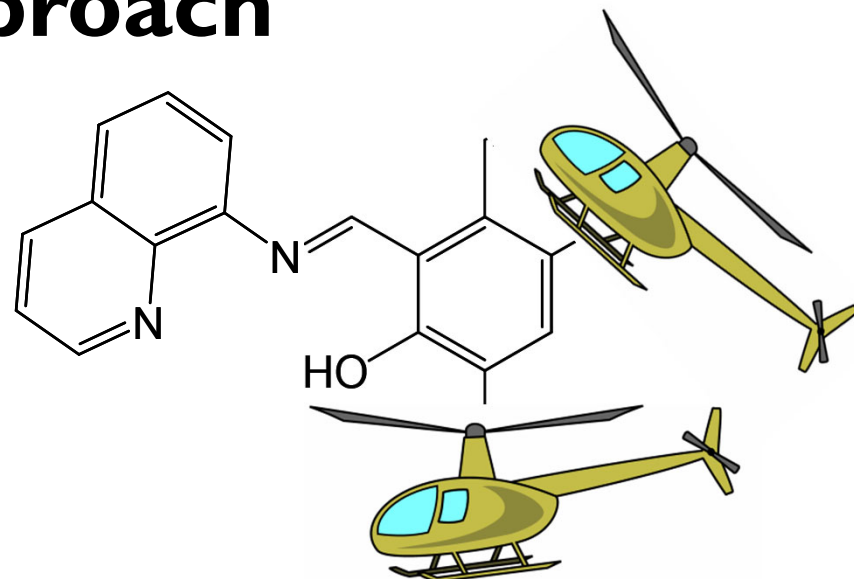
- neutral complexes
- easy synthetic modification
- asymmetric ligand structure
- only chelating (clamping) ligands



Synthetic Approach

Introduce the asymmetry of interactions to boost volatility

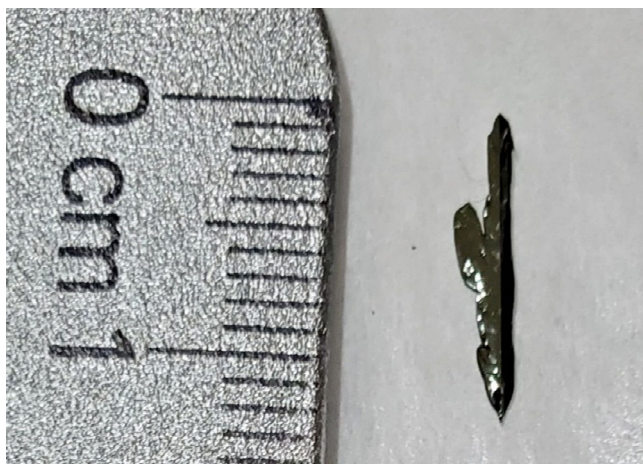
- the cooperativity will be preserved
- the volatility should be much higher



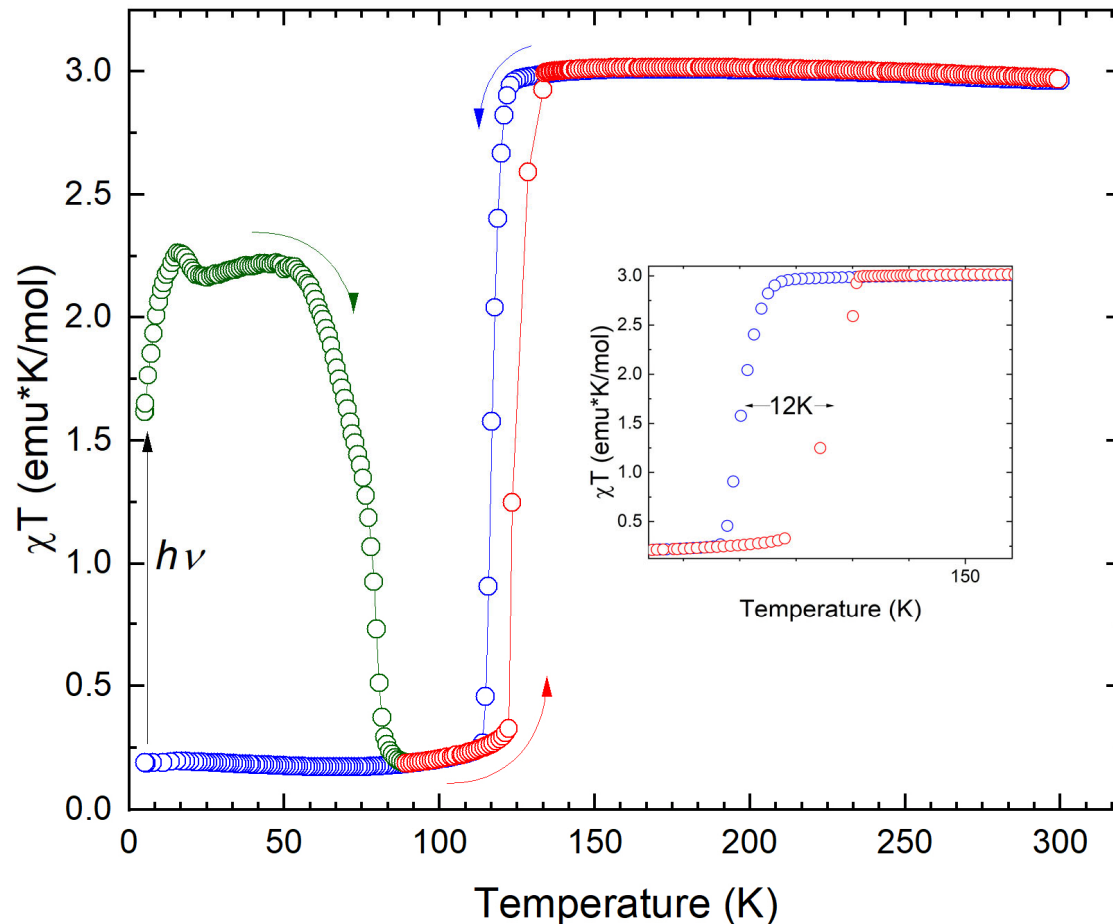
[Fe(tBu₂qsal)₂]



Properties of $[\text{Fe}(\text{tBu}_2\text{qsal})_2]$



Crystals grown
by vapor transport at
 $> 10^{-5}$ mbar & 300°C

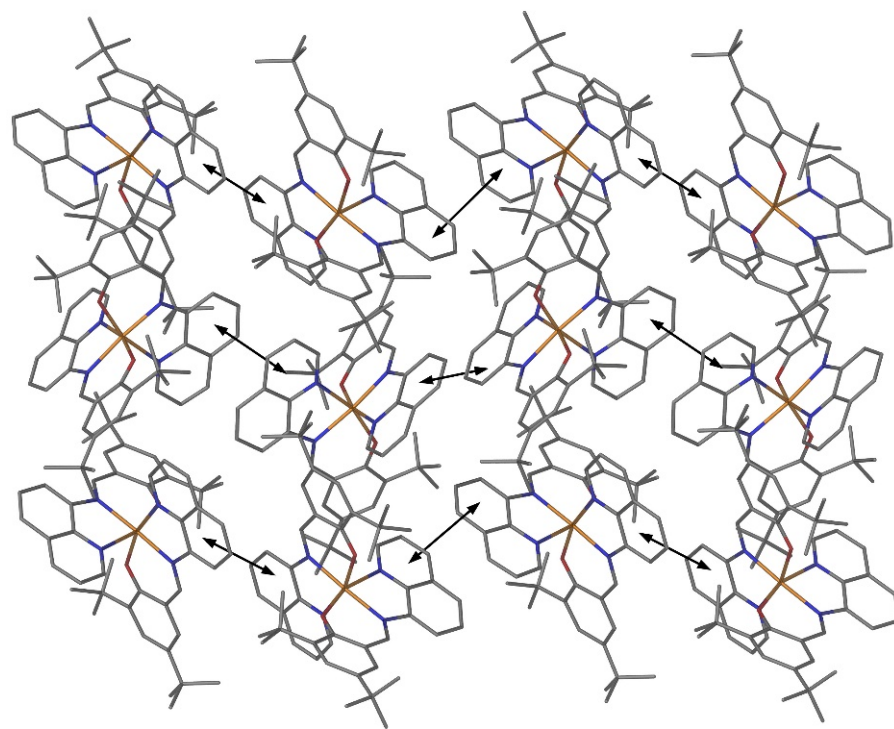
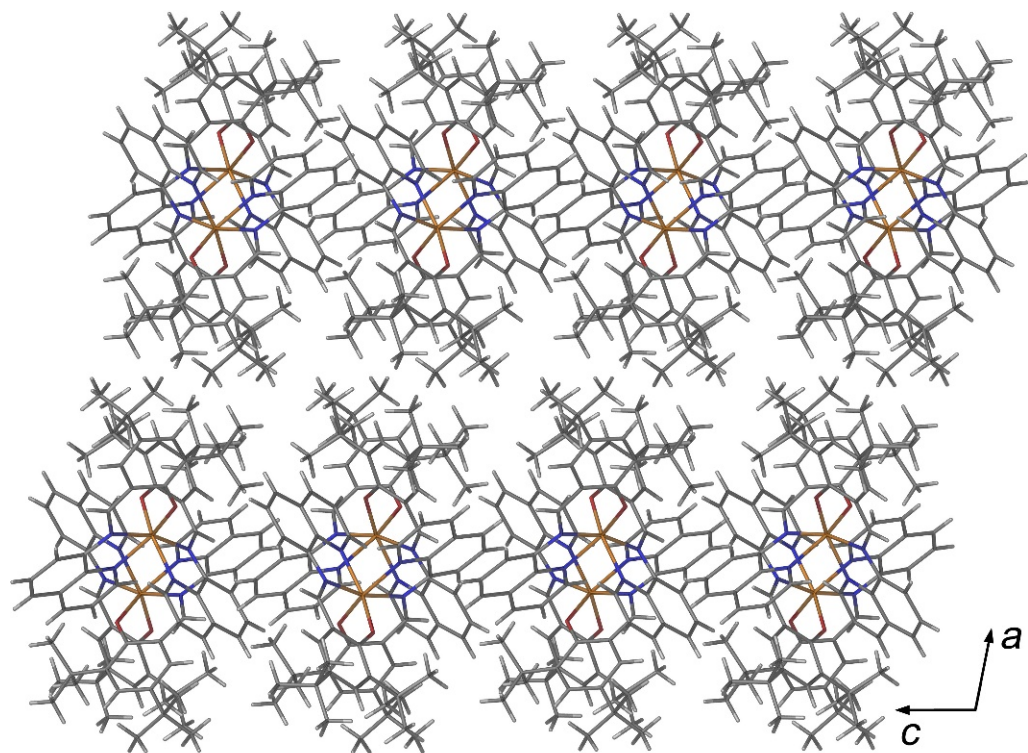


$$T_{1/2} = 117 \text{ K} / 129 \text{ K}$$

$$T_{\text{LIESST}} = 84 \text{ K}$$



Structural Anisotropy



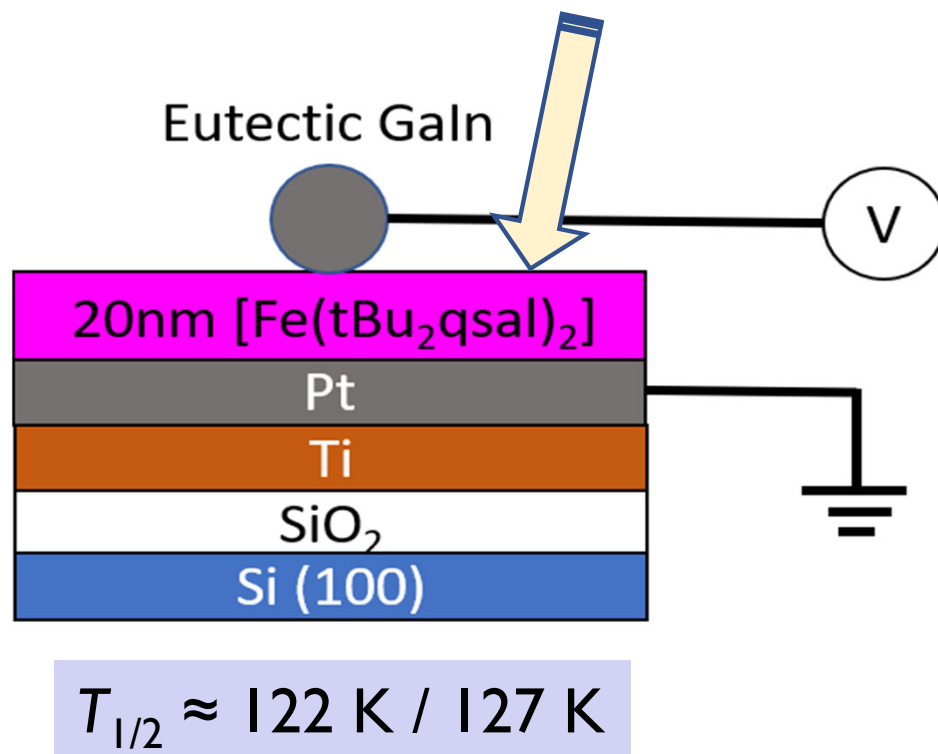
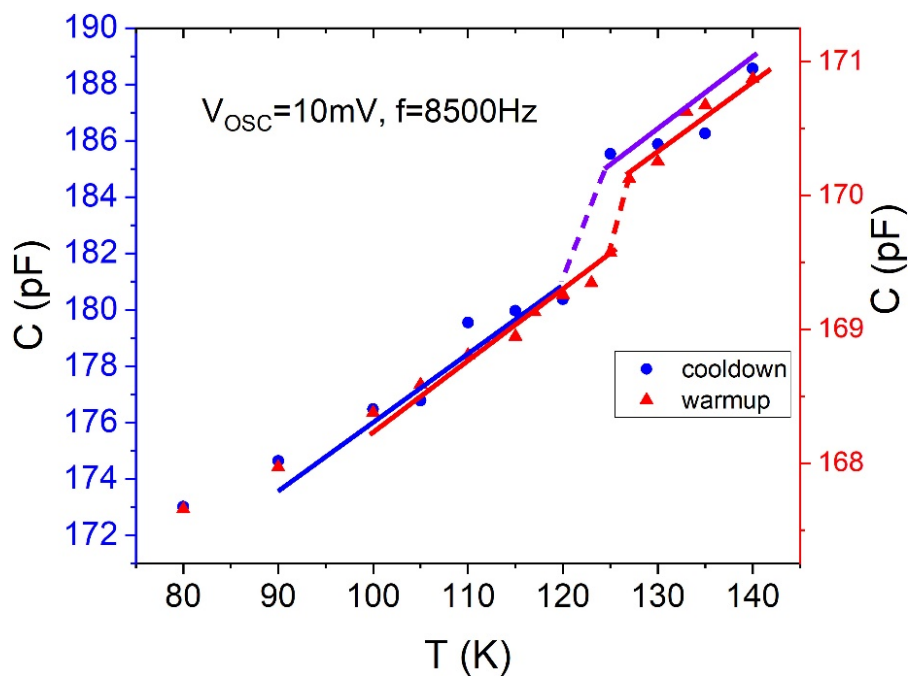
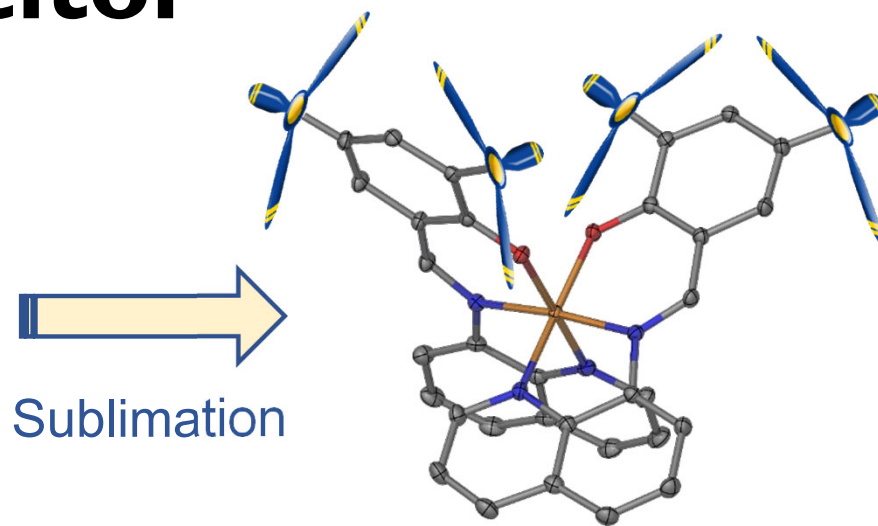
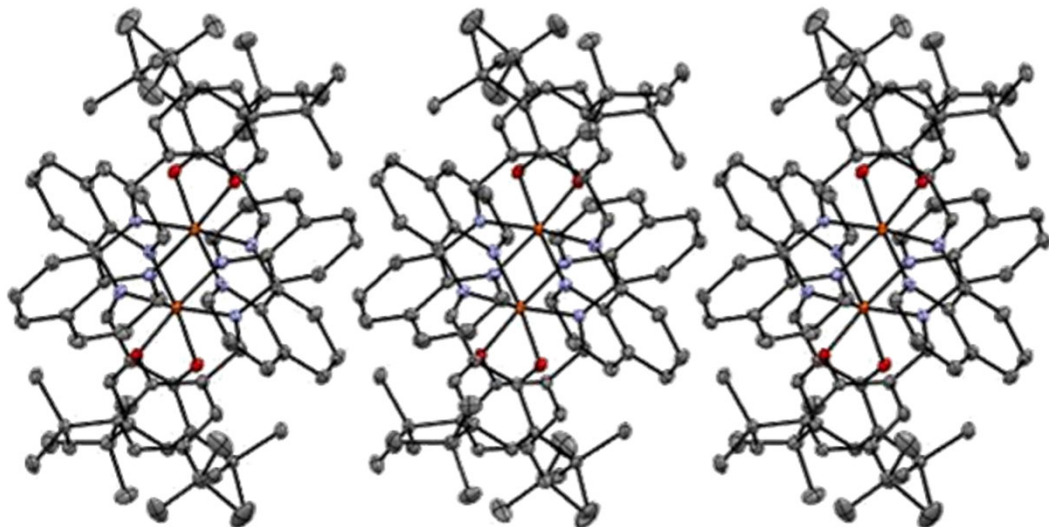
A single molecular layer

Calculated cohesion energies:

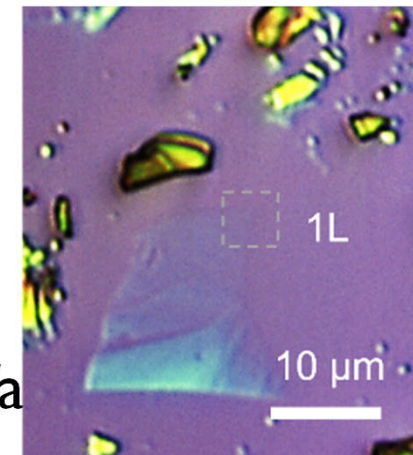
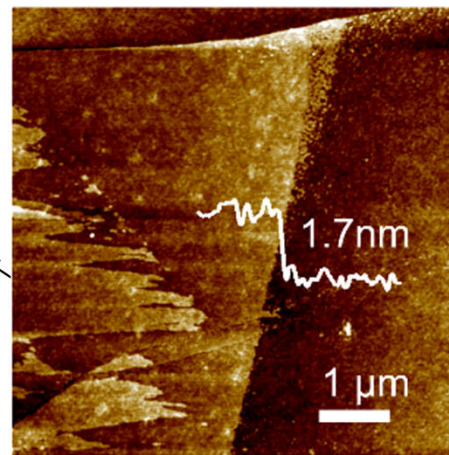
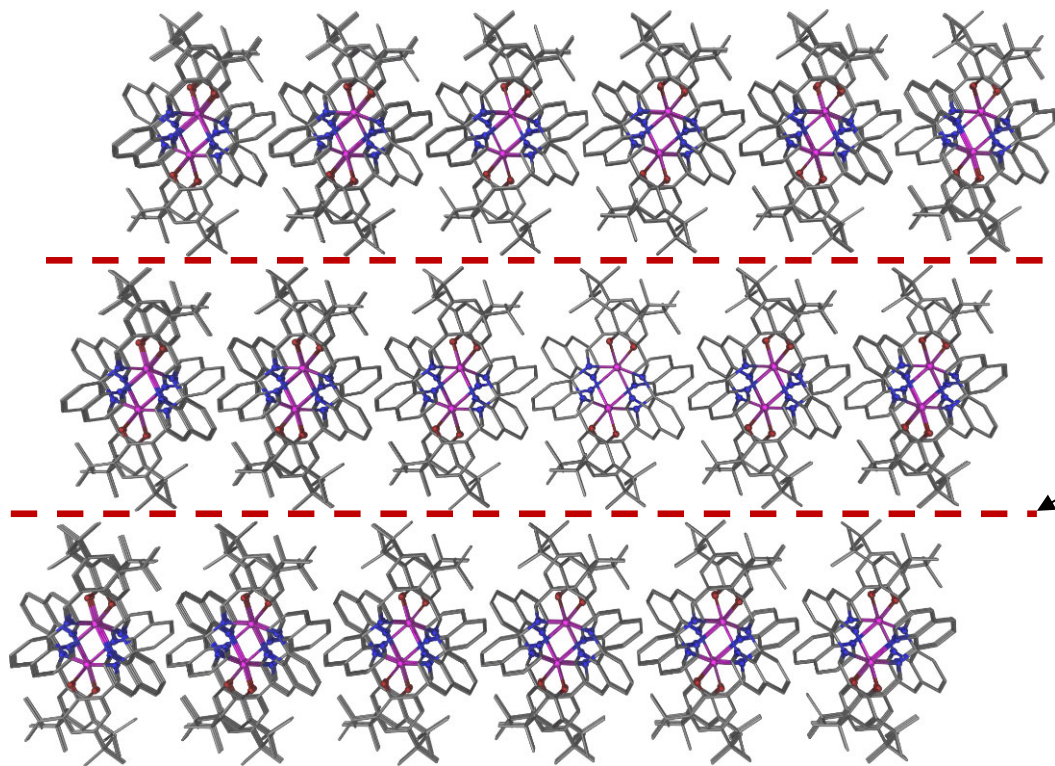
- 0.888 mJ/m² along [100]
- 0.927 mJ/m² along [001]
- 1.236 mJ/m² along [010]



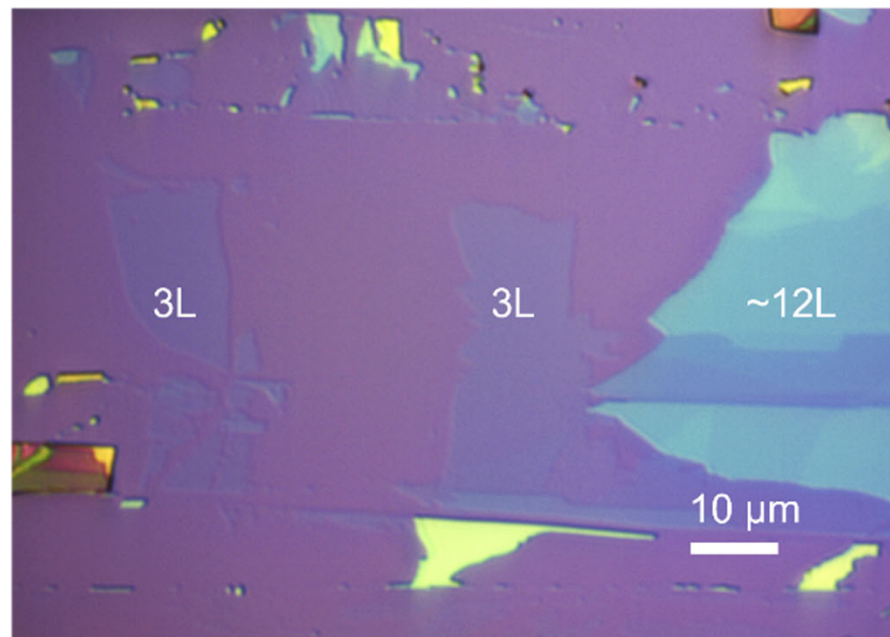
Thin-Film Capacitor



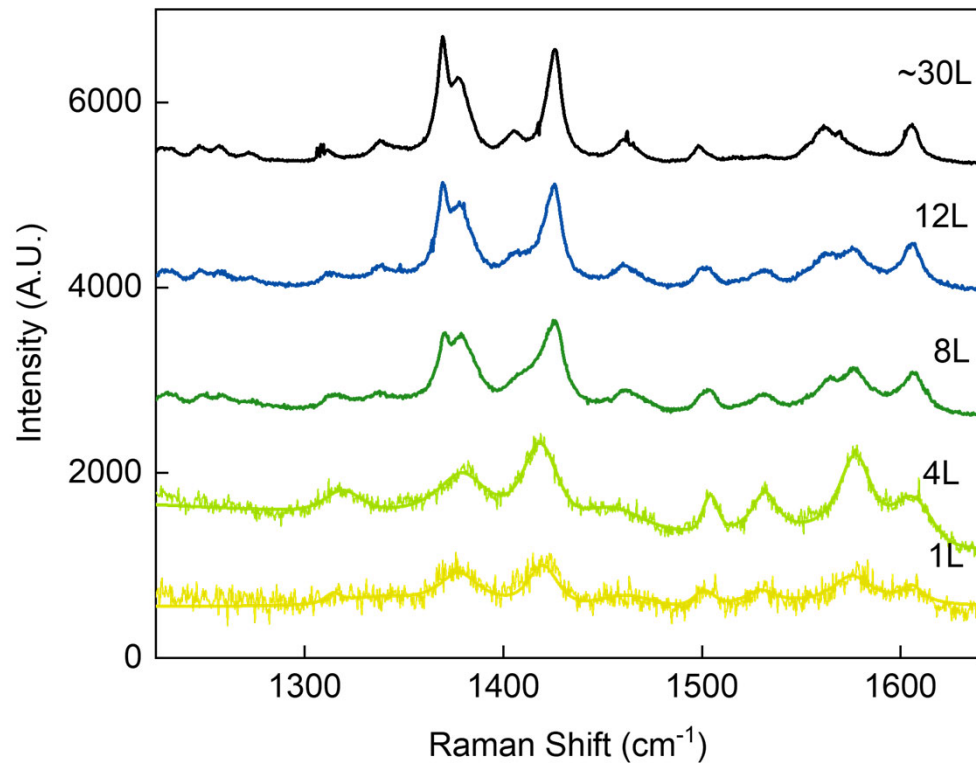
Mechanical Exfoliation



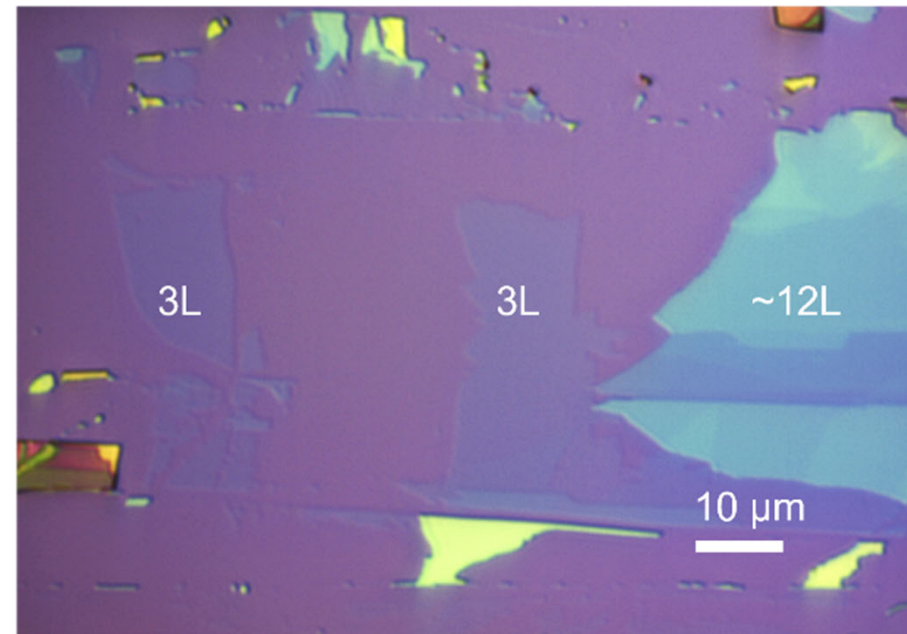
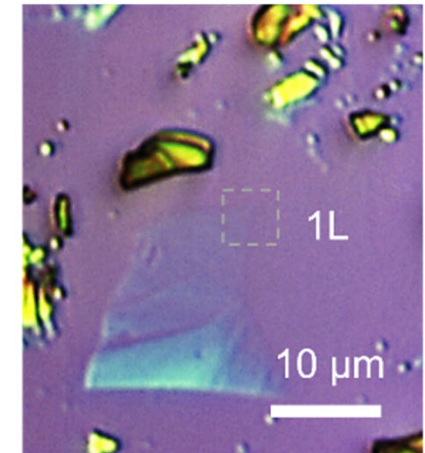
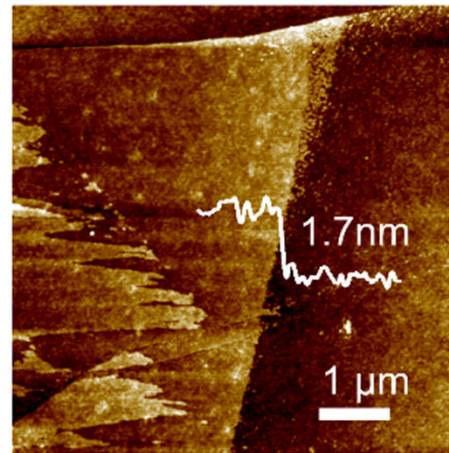
Successful exfoliation to
a single molecular layer
(1.7 nm thickness)



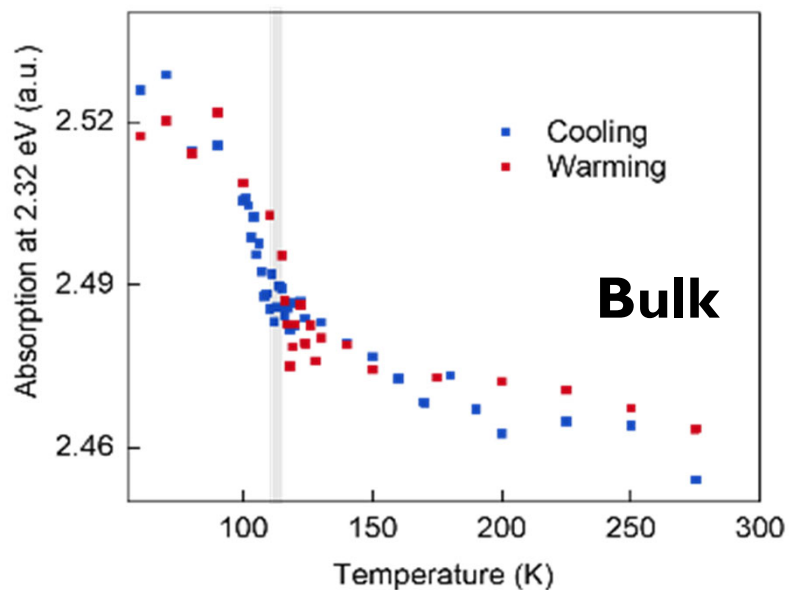
Mechanical Exfoliation



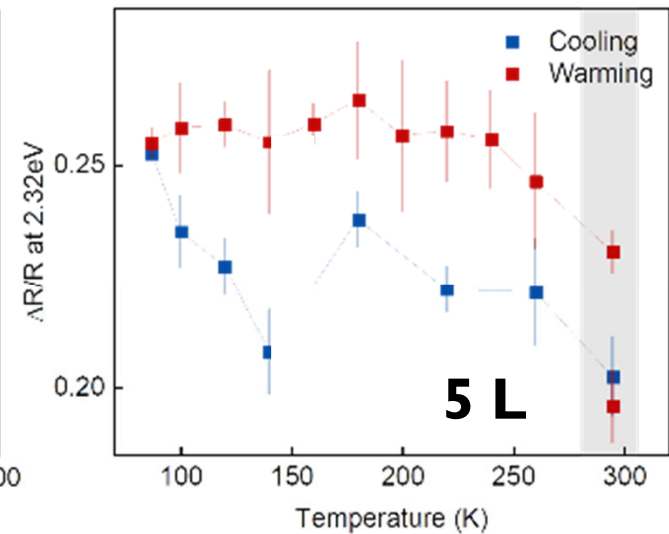
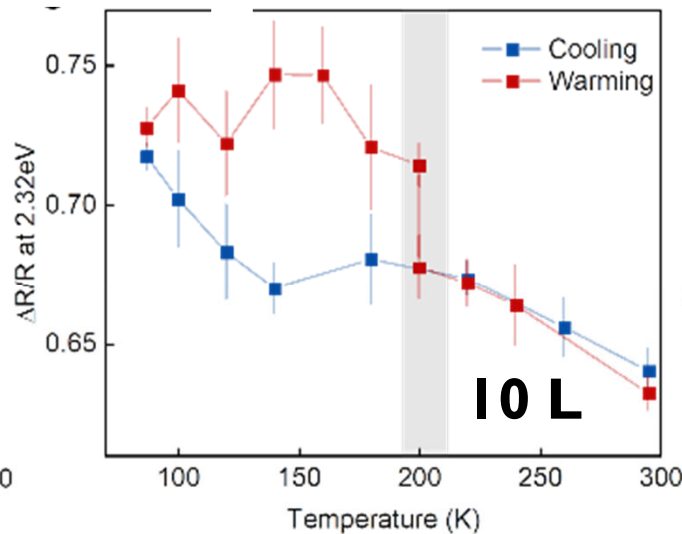
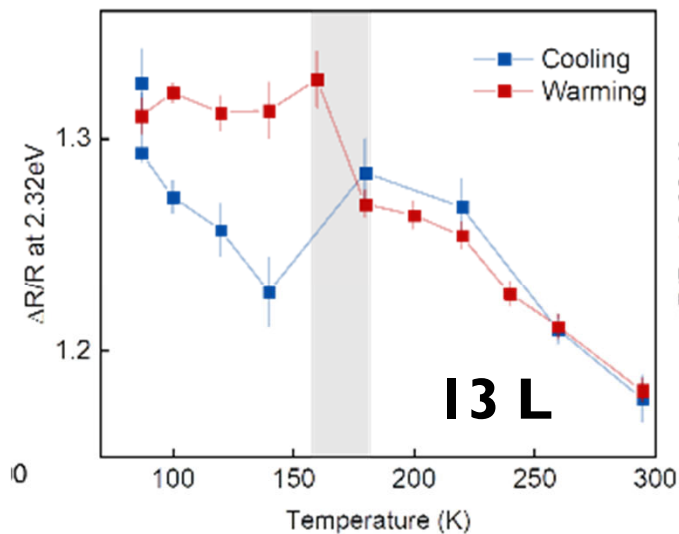
Successful exfoliation to
a single molecular layer
(1.7 nm thickness)



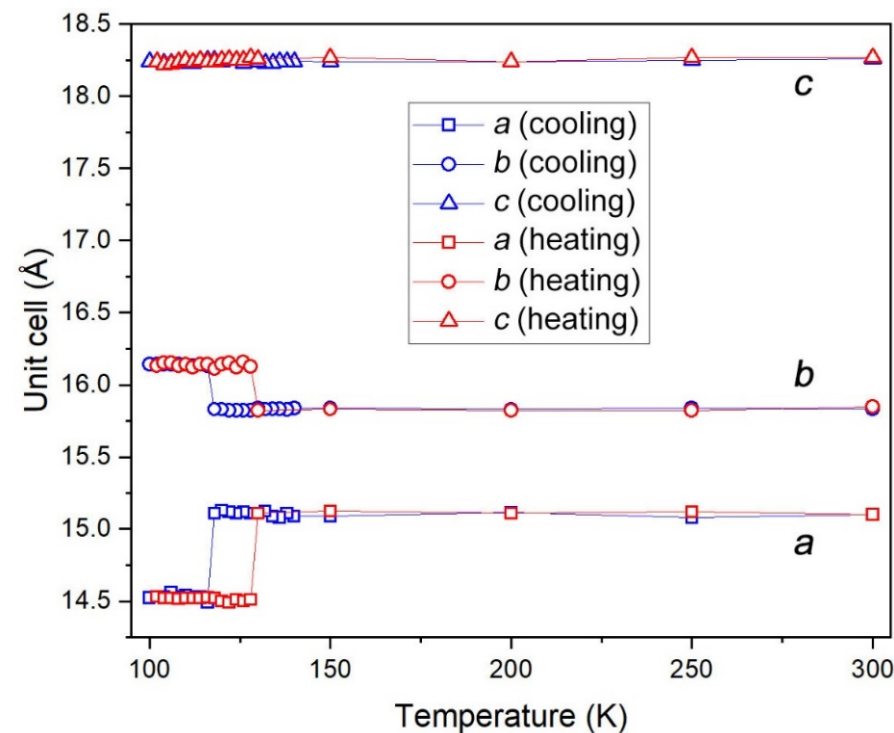
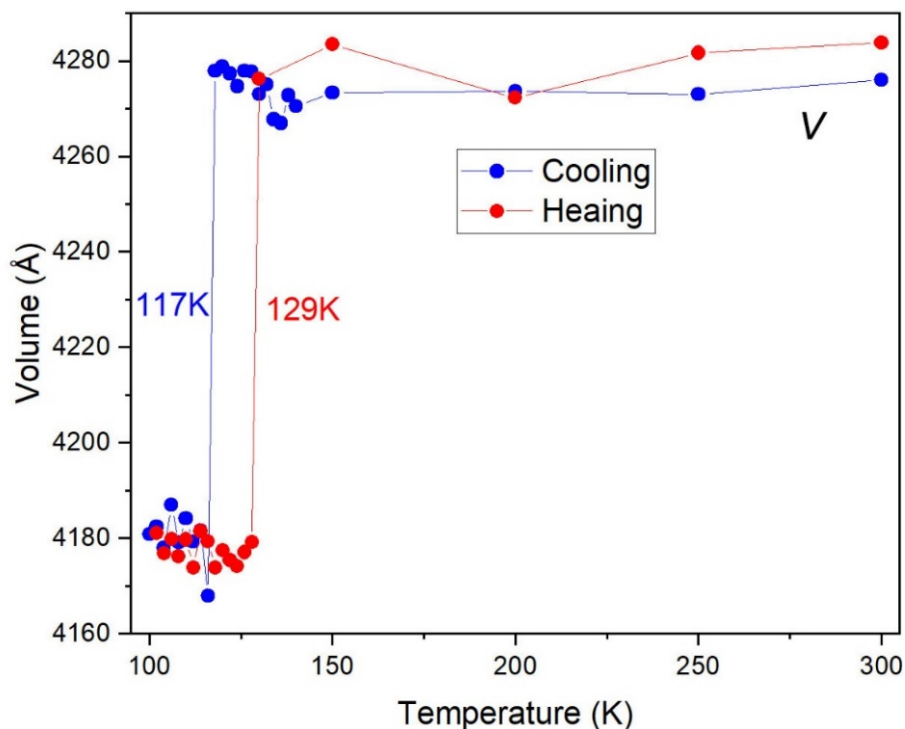
Thickness Dependence of SCO



The normalized reflection contrast measurements suggest increased hysteresis in the 2D SCO material



Thickness Dependence of SCO



# of layers	$\Delta T_{1/2}$
Bulk	12 K
13	~45 K
10	~90 K
5	~200 K

Hypothesized reason:

- Interfacial strain combined with the restriction of domain wall motion



Summary & Outlook

- Using the principle of asymmetric design, we can engineer increased volatility of materials while preserving the abrupt SCO
- The structural hierarchy allows mechanical exfoliation of ultrathin SCO flakes

Future Efforts

- Elucidating the role of substrates
- Extending the approach to other types of magnetic molecules (SMMs, radicals)
- Investigation of heterostructures and devices with inorganic 2D materials





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PDSTM-2027 in Tallahassee: The Capital of Florida & Magnets



**Oct 24-28
2027**